

MAINTENANCE MANUAL

MONITOR RECEIVERS TYPE ER-51-A & ER-52-A



SPECIFICATIONS *	25 — 50 MHz	132—174 MHz
Receiver Type	ER-51-A	ER-52-A
Channel Spacing	20 kHz (Narrow Band)	30 kHz (Narrow Band)
Sensitivity 12-dB SINAD 20-dB Quieting	0.25 μV 0.35 μV	0.3 μV 0.5 μV
Selectivity (EIA Two-Signal Method)	-60 dB	-80 dB
Spurious Response	-75 dB	-65 dB
Intermodulation (EIA)	-55 dB	-55 dB
First Oscillator Stability	$\pm .002\%$ (-30°C to +60°C, +25°C reference)	$\pm .001\%$ (-30°C to +60°C, +25°C reference)
Modulation Acceptance	±6 kHz	±7 kHz
Squelch Sensitivity	0.15 μV minimum 1.0 μV maximum	0.2 μV minimum 1.0 μV maximum

Frequency Response

Operable Temperature Range

Audio Output

Power Input

Maximum Frequency Separation

Within +2 dB and -8 dB of a 6 dB/octave de-emphasis curve from 300 to 3000 Hz (1000 Hz reference) per EIA standards

-30°C to +60°C (-22°F to +140°F)

1.5 watts at less than 10% distortion

20 watts at 117 VAC $\pm 10\%$, 50/60 Hz

0.4%

*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

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No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

EQUIPMENT INDEX

EQUIPMENT	MODEL OR TYPE NUMBER
25-50 MHz Receiver	ER-51-A
132-174 MHz Receiver	ER-52-A
Front Panel	19D402678-G1
Chassis	19C311011-G1
Top Cover	19A122161-G2
Standby Battery Supply	19B205435-G2
Channel Guard Decoder	4EK15A10
Bottom Cover (Support)	19B205283-G2

OPTIONAL EQUIPMENT

Type 99 Tone Decoder Boards A1403 & A1404 (One thru four boards, Options 4203 thru 4206)	19D413100-G1
Type 90 Tone Decoder Board A1701 (One thru four boards, Options 4207 thru 4210)	19C3O373O-G1
Audible Alarm, Option 4211 Buzzer and Second Relay	7136597-G2
Antenna Adaptor Cable, Option 4212	19A122312-G1
Carrier Operated Relay, Option 7610	19C303533-G2
132-174 MHz Indoor Antenna Option 4213 (Includes Connector M2R22-P2)	4EY19C10
Improved Intermodulation Modification, Option 5495	19A127250-G1

COMBINATION NOMENCLATURE

	Τ	1		T
8th & 9th Digit	11 25-33 MHz	22 33-42 MHz	33 42-50 MHz	132-150.8 MHz
7th Digit	Standard	Channel Guard	· ·	
6th Digit	A 1-Freq.	2-Freq.		
5th Digit	117-VAC	II7-VAC and Stby Battery	:	
4th Digit	20 kHz Channels	30 kHz Channels		
3rd Digit	Standard	Two reeds	Four reeds Type 99	
2nd Digit	Standard	Type 99 Decoder	Type 90 Decoder	
lst Digit	Monitor Rcvr			

Figure 1 - Combination Nomenclature Chart

150.8-174 MHz

DESCRIPTION

General Electric Monitor Receivers are attractively styled, high performance FM receivers designed for operation in the 25—50 and 132—174 megahertz range. The receivers are fully transistorized -- utilizing silicon transistors for added reliability. The compact design of the units permits them to be easily mounted on a desk, shelf or table with room left over for books, papers, etc.

Optional decoder boards are available for use with the receiver so that the unit will operate in a two-way radio system employing Channel Guard, Type 90 and Type 99 Encoders.

The receiver normally operates from a 117 volt AC, 50/60 Hz source. An optional chassis-mounted standby battery supply is available to power the receiver for up to seven hours in the event of power failure. The receiver may also be operated from an external 12-volt battery if desired.

Combination numbers for the receiver are shown in the Combination Nomenclature Chart (Figure 1.)

OPERATION

RECEIVER

Operating controls for the Monitor Receiver include the VOLUME and SQUELCH controls located on the front panel, and an OFF-ON switch located at the rear of the unit.

Turn the receiver on by sliding the OFF-ON switch to the ON position. The green power-on light will glow when the power is on. Then turn the SQUELCH control all the way to the right. If the receiver is equipped with Channel Guard, Type 90 or Type 99 Tone Decoders, disable the decoder circuitry by placing the RESET-MONITOR switch in the MONITOR position. Always return the MONITOR switch to the center position after making all adjustments.

Adjust the VOLUME control until the hissing sound is easily heard but not annoyingly loud. Next, turn the SQUELCH control slowly to the left until the hissing sound just fades out.

In two-frequency receivers, select the proper frequency (Fl or F2). The receiver is now ready to monitor two-way radios in the system.

CHANNEL GUARD

The operating control for the Channel Guard Decoder consists of a RESET-MONITOR switch located on the front panel. The decoder keeps all signals on the channel locked out of the Monitor Receiver except those that are continuously tone coded for positive identification by the decoder.

When a signal that is modulated by the proper tone code is received, the receiver audio circuits operate. Placing the RESET-MONITOR switch in the MONITOR position disables the Channel Guard Decoder, and permits all calls on the channel to be heard.

TYPE 90 & TYPE 99 TONE DECODERS

Operating controls for the Type 90 and Type 99 Tone Decoders include a RESET-MONI-TOR switch and an amber Call light located on the front panel.

When a properly tone-coded signal is received, the Call lamp lights and the message is heard in the speaker. After the message is completed, momentarily placing the RESET-MONITOR switch in the RESET position re-activates the decoder circuitry.

Placing the switch in the MONITOR position disables the decoder circuitry and permits all calls on the channel to be heard. Always return the RESET-MONITOR switch to the center position after monitoring the channel so that the receiver will operate normally.

CIRCUIT ANALYSIS

RECEIVER

Receiver Types ER-51-A $(25-50~\mathrm{MHz})$ and ER-52-A $(132-174~\mathrm{MHz})$ are double conversion, superheterodyne receivers designed for operation with the General Electric Monitor Receiver.

Each receiver consists of a receiver board and a 1st oscillator board. The frequency ranges and number of frequencies for the receivers are shown in the following chart.

RECEIVER TYPE NO.	RECEIVER BOARD	1ST OSCILLATOR BOARD	FREQUENCY RANGE	NUMBER OF FREQUENCIES
ER-51-A	19D402429-G1 19D402429-G1 19D402429-G2 19D402429-G2 19D402429-G3 19D402429-G3	4EG19A10 4EG19A11 4EG19A10 4EG19A11 4EG19A10 4EG19A11	25-33 MHz 25-33 MHz 33-42 MHz 33-42 MHz 42-50 MHz 42-50 MHz	One Frequency Two Frequency One Frequency Two Frequency One Frequency Two Frequency
ER-52-A	19D402257-G1 19D402257-G1 19D402257-G1 19D402257-G1	4EG20A10 4EG20A11 4EG20A12 4EG20A13	132-150.8 MHz 132-150.8 MHz 150.8-174 MHz 150.8-174 MHz	One Frequency Two Frequency One Frequency Two Frequency

The audio PA stage is mounted on the main chassis, and the loud-speaker is mounted on the front panel. The unit is completely transistorized -- utilizing 17 silicon transistors, seven silicon diodes and two zener diodes. An additional transistor is added for two-frequency operation.

A centralized metering jack (J312) is provided for use with General Electric Test Set TM11 or TM12 (Model 4EX3A10) for aligning and servicing the receiver. The Test Set meters the limiter stages, oscillator, supply voltages, voice coil, PA and discriminator stages.

VOLTAGE REGULATOR

The receiver operates on a regulated 10 volts provided by Q315 and Q316 in a series regulator circuit.

When the input voltage at J311 starts to rise, the output voltage at the emitter of Q315 also tries to rise. This changes the base-emitter bias on Q316, causing it to conduct more heavily. When Q316 conducts, there is less base bias on Q315 and, therefore, less base current flows through the transistor. With less base current flowing, the voltage drop across Q315 is larger and less voltage appears at the output.

When the input voltage starts to drop, Q316 conducts less, increasing the forward bias on Q315. The increased forward bias decreases the voltage drop across Q315, and more voltage appears at the output. Regulation will stop if the input value drops below 11 volts.

The 10-volt REGULATOR adjustment (R372/R373) is set for a 10-volt reading at centralized metering jack J312 when aligning the receiver.

RF AMPLIFIER

RF signals from the antenna are fed to the base of low noise RF amplifier Q301 through two tuned pre-selector circuits.

The output of the RF amplifier is coupled through two tuned circuits to the base of the lst mixer.

OSCILLATOR/MULTIPLIER

In 25-50 MHz receivers, Q425 is a Colpitts oscillator operating in the 12 to 19 megahertz range. Trimmer capacitor C425 permits the oscillator frequency to be shifted slightly for setting the receiver on the system operating frequency.

For 25 to 33 megahertz operation, collector coil L425 is tuned to two times the crystal frequency with high-side injection. For 33 to 42 megahertz operation, L425 is tuned to two times the crystal frequency with low-side injection. For 42 to three times the crystal frequency with low-side injection.

In 132-174 MHz receivers, Q425 is a third mode oscillator that operates in the 49 to 54 megahertz region. The crystal is connected in the oscillator feedback path to permit oscillation only at the crystal frequency. L425, C425, C426 and C428 make up the mode selective resonant circuit. Adjustable coil L425 permits the oscillator frequency to be shifted slightly for setting the receiver on the system operating frequency. The collector tank of A425 is tuned to three times the crystal frequency.

For two-frequency operation, a second oscillator/multiplier stage is added. Channels are selected by grounding the emitter of the desired oscillator by means of a two-frequency switch on the front panel.

1ST MIXER

RF signals from the RF amplifier are fed to the base of 1st Mixer Q302 along with the oscillator injection frequency. The Hi IF mixer output is fed to a three-coil torroidal Hi IF filter and then fed to the base of 2nd mixer Q304.

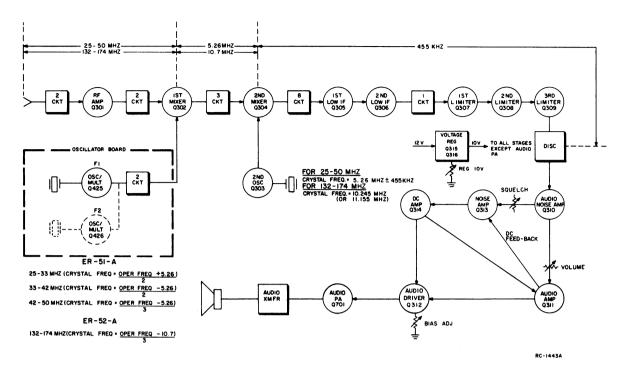


Figure 2 - Receiver Block Diagram

2ND OSCILLATOR AND MIXER

Q303 operates as a Pierce oscillator with a crystal frequency of 3.26 megahertz ± 455 kHz for low band or 10.245 (or 11.155) megahertz for high band.

Hi IF from the 1st mixer is applied to the base of 2nd mixer Q304. This Hi IF is mixed with the 2nd oscillator low side (or high side) injection frequency which produces the 455-kilohertz Lo IF. The main receiver selectivity is provided by the eight-coil Lo IF filter following the 2nd mixer.

LO IF AMPLIFIERS

Two RC-coupled Lo IF amplifiers (Q305 and Q306) are used to amplify the signal going to the limiter stages. The amplifier output is coupled to the 1st limiter through a 455-kHz filter (L316 and C348), which reduces the noise bandwidth of the IF string.

LIMITERS

Following the Low IF amplifiers are three RC-coupled limiter stages, Q307, Q308 and Q309, which operate as over-driven amplifiers. Zener diode CR308 provides additional limiting. The 1st and 2nd limiter stages are metered at the centralized metering jack (J312) through metering diodes CR301 and CR302.

DISCRIMINATOR

The limiter output is applied to the Foster-Seely type discriminator, where the audio voltages are recovered from the 455-kHz Lo IF. A Lo IF filter removes any 455-kHz signal remaining in the discriminator output.

AUDIO AMPLIFIERS

When audio is present in the incoming signal, it is fed to the base of audio-noise amplifier Q310. Following Q310 is an audio de-emphasis network.

After the de-emphasis network, audio is fed to the base of audio amplifier Q311 through the volume control mounted on the front panel. The VOLUME control sets the amount of drive to the audio stages. An audio driver (Q312) and an audio PA output stage (Q701) follow audio amplifier Q311. Audio Bias trimmer R366/R367 sets the bias on Q312 and Q701, and is adjusted for a 250-millivolt reading at metering jack J312. The output of Q701 drives the loudspeaker.

SQUELCH

Noise from audio-noise amplifier Q310 is used to operate the squelch circuit. When no carrier is present in the receiver, this noise is coupled through a noise filter (which attenuates any audio frequencies) to the base of noise amplifier Q313. The noise level fed to the noise amplifier is set by the SQUELCH control, located on the

control unit. The output of noise amplifier Q313 is rectified by diodes CR305 and CR306, to produce a positive DC voltage. This DC voltage turns on the DC amplifier (Q314), causing it to conduct. When conducting, the collector voltage of the DC amplifier drops to ground potential, which removes the bias on the audio stages and turns them off.

When audio amplifier Q311 is being turned off, its emitter potential decreases. This results in a positive DC feedback through R351/R352 to the emitter of noise amplifier Q313 which causes an increase in the gain. As the gain of Q313 increases, the positive DC voltage to the DC amplifier increases, turning the audio stages off quickly.

When the receiver is quieted by a signal, less noise is present in the circuit and DC amplifier Q314 stays off. The audio stages are allowed to conduct and audio is heard from the speaker. With audio amplifier Q311 conducting, positive voltage appears across R351/R352 which helps reduce the gain of noise amplifier Q313. The positive feedback causes a quick, positive switching action in the squelch circuit.

POWER SUPPLY

The Monitor Receiver has a self-contained power supply designed to operate from a 117-volt AC, 50/60 Hz source. The power supply consists of a full-wave rectifier (CR701 and CR702) for rectifying the AC voltage developed across the secondary of step-down transformer T701. The primary of T701 is protected by a 1/4-amp slow-blow fuse (F701).

The output of the rectifiers is filtered by C701, L701 and C702 to provide +12 volts DC for operating the receiver, audio PA stage and the tone options.

The power-on indicator light is operated by an unfiltered +12 volts.

OPTIONS

CHANNEL GUARD DECODER

The Channel Guard decoder is designed to eliminate all calls that are not tone coded for the Channel Guard frequency. Normally, all signals are locked out except those from transmitters that are continuously tone-coded for positive identification by the receiver. Placing the Monitor switch S704 in the MONITOR position, instantly disables the Channel Guard circuit and the receiver operates on noise squelch only. For complete operating and maintenence information, refer to the Maintenance Manual for the decoder LBI-3802.

TYPE 90 AND TYPE 99 DECODERS

A maximum of four tone decoder boards with single relays or two decoder boards with two relays can be used with the Monitor Receiver.

The basic decoder board is supplied with one output relay. When a signal modulated by a pulse tone (Type 90) or sequential tone (Type 99) is received from the receiver discriminator, the relay locks up and the Call light turns on, and the message is heard in the speaker. Placing the RESET-MONITOR switch (S703) in the RESET position unlocks the relay and cuts off the Call light. If desired, one set of relay contacts can be used to activate an external alarm. An optional second relay and buzzer is available for use with the tone decoders. A description of the option is contained in the following section. For complete, operating and maintenance information concerning the Type 90 Tone Decoder refer to LBI-3684 or for Type 99 Tone Decoder refer to LBI-3839.

AUDIBLE ALARM

An Audible Alarm, consisting of a buzzer and second relay, can be used with the Type 90 and Type 99 Decoders. The relay plugs into the socket provided on the decoder board, and the buzzer mounts on the under side of the chassis as shown on the chassis Outline Diagram.

When the Audible Alarm option is used, the output relay can be connected for timed operation (3 to 5 seconds). The second relay operates locked to the RESET switch. The buzzer operates from the timed relay.

STANDBY BATTERY SUPPLY

The Standby Battery Supply is available for providing up to seven hours of operation in the event of power failure. The Battery Supply mounts on the chassis of the Monitor Receiver, and consists of a voltage-regulated taper charging circuit, a change-over relay and two rechargeable nickel-cadmium batteries. A maximum of two Type 90 or Type 99 Tone Decoders can be mounted on the Monitor Receiver chassis when the Standby Battery Supply is used.

Turning OFF-ON switch S701 to the ON position applies 117 VAC to the primary of stepdown transformer T1, and +12 volts to energize relay K1. The AC voltage developed across the secondary of T1 is rectified by the full-wave rectifier CR1 and CR2 and filtered by R1, R2 and C1. R1 and R2 also serve as charging current limiting resistors when the two batteries, BT1 and BT2, are in a discharged condition.

Dropping resistor R4, provides the negative bias to turn on Q1. Zener diode VR1

provides a voltage reference for the regulator.

When the input voltage at H7 rises, the output voltage at the emitter of Q1 also tends to rise. This causes a change in the base-emitter bias on Q2 making it conduct more heavily. When Q2 conducts, there is less base bias on Q1, and less base current. With less base current, the voltage drop across Q1 is larger, and the output voltage remains constant.

When the input voltage starts to drop, the output voltage also tends to drop, causing Q2 to conduct less. This increases the forward bias of Q1 and reduces the voltage drop across the transistor so that the output voltage remains constant. R5, R6 and R7 form an adjustable voltage divider so that potentiometer R6 can be adjusted for a 16.65-volt output. R3 provides bias current for VR1. The output is metered between H5 (+) and H4 (-) with the batteries disconnected.

If the batteries BT1 and BT2 are in a discharged condition, the charging current will be at a maximum since the regulator is supplying a constant voltage. The charging current will decrease as the batteries become fully charged until finally the batteries are receiving only a trickle charge.

In the event of a power failure, the relay is de-energized and the battery output is applied through K1-11 to operate the receiver. Diode CR2 prevents the pilot light (DS701) from lighting. Resistor R2 is switched in series with the emitter resistor of the audio PA stage (Q701), which reduces the audio output to approximately 150 milliwatts. When fully charged, the batteries will operate the receiver for approximately seven hours on a 10% receive, 90% squelched duty cycle.

CARRIER OPERATED RELAY

The Carrier Operated Relay assembly provides four form C contacts for controlling external circuits whenever a carrier is applied to the receiver.

When a carrier unsquelches the receiver, a positive voltage (approximately 2 volts) from the base of the receiver audio amplifier transistor turns on Ql in the carrier operated relay circuit. Current flow in the collector circuit of Ql forward biases Q2, causing it to conduct and energize relay Kl. Voltage "spikes" produced across Kl (when Kl deenergizes) are absorbed by diode CRl to prevent damage to transistors Q1 & Q2.

IMPROVED INTERMODULATION

The Improved Intermodulation modification is available for use with 132-174 MHz

receivers to provide a 60 dB intermodulation response (EIA) with some loss in receive sensitivity. The modification consists of replacing the RF Amplifier circuit in the receiver front end with trimmer C2351 (see Figure 3).

Trimmer C2351 permits tuning the receiver to trade off sensitivity for improved intermodulation protection. The trimmer can be tuned for a 20 dB quieting sensitivity of 0.8 to 1.5 microvolts (0.6 to 1.2 microvolts for 12 dB SINAD). Instructions for adjusting C2351 are contained on the Receiver Alignment Procedure (see Table of Contents).

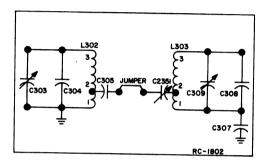


Figure 3
Improved Intermodulation Modification

ADJUSTMENT

RECEIVER

After the Monitor Receiver has been installed, the receiver should be set on the system operating frequency, and the antenna transformer matched to the antenna. Refer to the Front End Alignment on the RECEIVER ALIGNMENT PROCEDURE as listed in the Table of Contents.

DECODERS

No adjustments are required on the Channel Guard, Type 90 or Type 99 Decoders.

STANDBY BATTERY SUPPLY

Potentiometer R6 is adjusted and secured with a sealant at the factory to prevent tampering. However, if either VR1 or Q2 is replaced, it is recommended that R6 be replaced to facilitate adjustment. If it becomes necessary to adjust R6 and no replacement part is available, the sealant may be loosened by heating the metal ring on R6 with a soldering iron while making

the adjustment. This procedure requires a DC-VTVM that is accurate to $\pm .02$ volts.

- CAUTION -

Failure to set the output voltage with R6 to 16.65 volts ±.02 volts may result in an insufficient charge or damage to the batteries.

SET R6 AS FOLLOWS:

- 1. Disconnect BT1 and BT2.
- Connect the positive meter lead to the positive charging terminal (H5) and the negative meter lead to the negative charging terminal (H4) on the standby battery supply board.
- Turn on switch S701 and adjust R6 for a voltage reading of 16.65 volts.
- Turn off switch S701 and secure R6 with cement (Loctite R404 or equivalent).

MAINTENANCE

TEST AND TROUBLESHOOTING PROCEDURES

Whenever difficult servicing problems

occur, the test procedure for the receiver can be used by the serviceman to compare actual performance of the unit against the specifications met by the unit when shipped from the factory. The Test Procedure is described on the back of the Receiver Alignment Procedure.

In addition, a Receiver Troubleshooting Procedure is available. (Refer to the Table of Contents). For best results, the test procedure should be used in conjunction with the troubleshooting procedure.

Refer to the applicable Maintenance Manual for servicing the Type 90 or Type 99 Tone Decoders.

DISASSEMBLY

To gain access to the Monitor Receiver for servicing, loosen the two captive knurled screws in the back of the unit and lift off the top cover.

- NOTE -

If it should become necessary to replace the audio PA transistor (Q701), make sure that there is a thin layer of silicon grease on each side of the insulator before remounting the transistor.

FRONT END ALIGNMENT

These instructions are for tuning the oscillator and RF stages of the receiver and may be used when changing the receiver crystal or frequency. When necessary to realign the entire receiver, refer to the COMPLETE RECEIVER ALIGNMENT.

EQUIPMENT REQUIRED

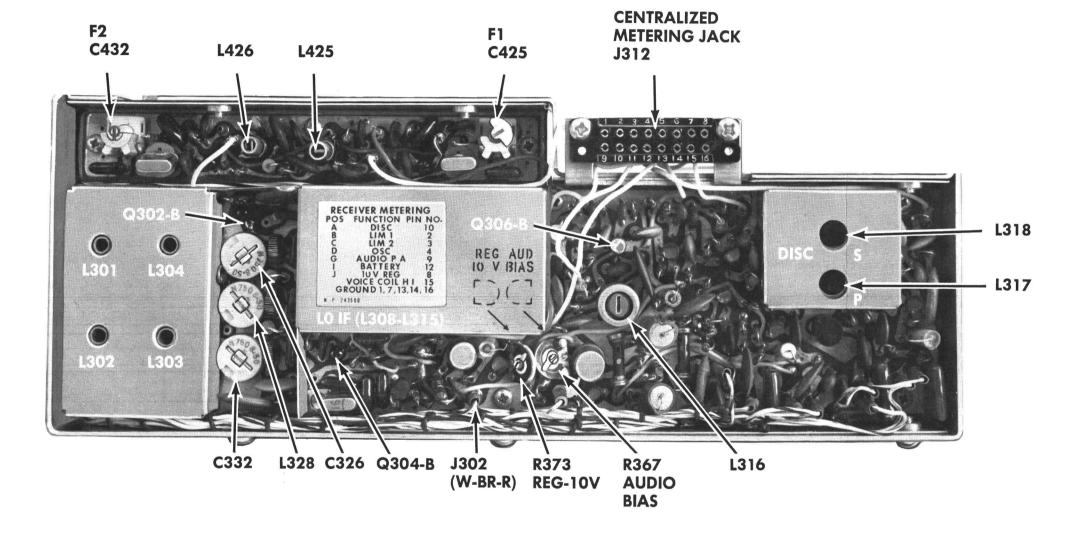
- 1. G-E Test Set Model TM11 or TM12 (or 20,000 ohms-per-volt Multimeter).
- 2. A 25-50 mHz Signal Source. Keep signal level below saturation.

PRELIMINARY CHECKS AND ADJUSTMENTS

- 1. Plug in the Test Set to the receiver centralized metering jack J312. Set Meter Polarity Switch on + and Meter Sensitivity Switch to 1. If using Multimeter, connect the negative lead to J312-13 (ground).
- Switch Test Set to Position "I" (or measure at J302 with Multimeter). Reading should be at least 12 volts.
- 3. Switch to Position "J" (or measure across R373 with Multimeter) and adjust Voltage Regulation Potentiometer R373 for a reading of 10 volts.
- 4. Turn SQUELCH control fully clockwise and VOLUME control to minimum. Switch to Position "G" (or measure at J312-9 with Multimeter) and adjust Audio Bias Potentiometer R367 to a reading of 0.25 volt.

ALIGNMENT PROCEDURE

	T				
STEP	METERIN 4EX3A10	Multimeter + at J312	TUNING CONTROL	METER READING	PROCEDURE
1.	D OSC	Pin 4	C425 (and C432 for two-fre- quency), L425 and L426	See Proce- dure	Tune C425 (and C432 for two-frequency) and L425 for maximum meter reading. Then tune L426 for minimum meter reading. NOTE Start tuning procedure with the slugs fully in on 25-42 mHz units and fully out on 42-50 mHz units.
2.	C LIM-2	Pin 3	L301 thru L304	Maximum	Apply an on-frequency signal to Antenna Jack and tune L301 through L304 for maximum meter reading.
3.			L301 and L302	See Proce- dure	While receiving a weak on-frequency signal at the Antenna, tune L301 and L302 for maximum quieting.
4.	A DISC	Pin 10	C425 (and C432 for two-fre- quency)	Zero	Apply an on-frequency signal to Antenna Jack and tune C425 (and C432 for two-frequency) for zero discriminator reading.



EQUIPMENT REQUIRED COMPLETE RECEIVER ALIGNMENT

- 1. G-E Test Set Model TM11 or TM12 (or 20,000 ohms-per-volt Multimeter).
- 2. A 455 kHz, a 5.26 mHz and a 25-50 mHz Signal Source. Couple the 455 kHz signal through a small capacitor (approximately 100 pf). Couple the 5.26 mHz signal through a .01 μf capacitor. Keep signal levels below saturation.

PRELIMINARY CHECKS AND ADJUSTMENTS

METERING POSITION

- 1. Plug in the Test Set to the receiver centralized metering jack J312. Set Meter Polarity Switch on + and Meter Sensitivity Switch to TEST 1.
 If using Multimeter, connect the negative lead to J312-13 (ground).
- 2. Switch Test Set to Position "I" (or measure at J302 with Multimeter). Reading should be at least 12 volts.
- 3. Switch to Position "J" (or measure across R373 with Multimeter) and adjust Voltage Regulation Potentiometer R373 for a reading of 10 volts.
- 4. Turn SQUELCH control fully clockwise and VOLUME control to minimum. Switch to Position "G" (or measure at J312-9 with Multimeter) and adjust Audio Bias Potentiometer R367 for a reading of 0.25 volt.

ALIGNMENT PROCEDURE

STEP		MULTIMETER + at J312	TUNING CONTROL	METER READING	PROCEDURE
				DISCRIMINA	ATOR
1.	C LIM-2	Pin 3		0.3 volt (1.1 v with Multimeter)	Apply a 455 kHz signal to the base of Q306 and adjust signal level for 0.3 volt meter reading (to saturate limiters).
2.	A DISC	Pin 10	L318	Zero	Apply a 455 kHz signal as above and adjust L318 (disc secondary) for zero meter reading.
3.	DISC A	Pin 10	L317 & L318	0.65 v (1.6 v with Multimeter)	Alternately apply a 445 kHz and 465 kHz signal while adjusting L317 and L318 for readings of at least 0.65 volt. Both readings should be within 10%.
4.	B LIM-1	Pin 2	L316	Maximum	Apply a 455 kHz signal as above, and tune L316 for maximum meter reading.
5.	osc	Pin 4	C425 (and C432 for two frequency) L425 and L426	See Procedure	Tune C425 (and C432 for two-frequency) and L425 for maximum meter reading. Then tune L426 for minimum meter reading. NOTE Start tuning procedure with the slugs fully in on 25-42 mHz units and fully out on 42-50 mHz units.
				HI IF	
6.	C LIM-2	Pin 3	C326, C328 and C332	Maximum	Apply a 5.26 signal to the base of Q302 or an <u>on-frequency</u> signal to Antenna Jack J701. Turn C326, C328 and C332 for maximum meter reading.
				LOW II	·**
7.	A DISC	Pin 10		Zero	Apply a 5.26 mHz signal to the base of Q304. Adjust the signal generator for discriminator zero.
8.	C LIM-2	Pin 3	L308 thru L315	Maximum	Apply signal as above. Peak L308 through L315 for maximum meter reading, keeping signal below saturation.
9.			L308 thru L315		Connect oscilloscope to Pin 2 and Pin 13 (Ground) to centralized metering jack J312. Modulate signal generator with at least ±30 kHz deviation with 60 Hertz (or less). Tune L308 through L315 for filter pattern as shown, keeping signal level below saturation.
					The above filter alignment should result in the center of the bandpass at 455 kHz ± 1 kHz $(\pm 0.7 \text{ volt}$ reading with meter in Position A), with a EIA modulation acceptance of ± 6 to ± 10 kHz.
				RF	
10.	C LIM-2	Pin 3	L301 thru L304	Maximum	Apply an on-frequency signal to Antenna Jack and tune L301 through L304 for maximum meter reading.
11.		A S	L301 and L302	See Procedure	While receiving a weak on-frequency signal at the Antenna, tune L301 and L302 for maximum quieting.
				FREQUENCY ADJ	JUSTMENT
12.	A	Pin 10	C425 (and C432 for two-frequency)	Zero	Apply an on-frequency signal to Antenna Jack and tune C425 (and C432 for two-frequency) for zero discriminator reading.

* NOTE — Low IF coils L308 through L315 have been set at the factory and will normally require no further adjustment. Do NOT realign the filter unless there is positive evidence of a defective filter. For location of IF coils, refer to the Receiver Service Sheet.

ALIGNMENT PROCEDURE

25—50 MHz RECEIVER TYPE ER-51-A

LBI-3757

(RC-1475B)

RECEIVER TEST PROCEDURES

steps starting with Step 1, the defect can be quickly localized. Once operating frequency.

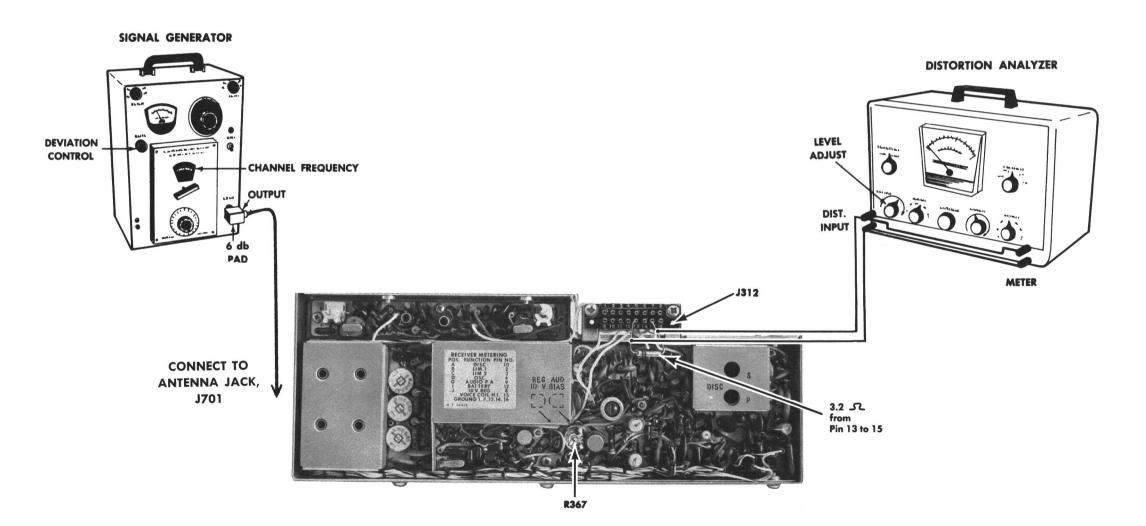
The Receiver Test Procedures are designed to help you to service the defective stage is pin-pointed, refer to the "Service Check" listed a receiver that is operating — but not properly. The problems en- to correct the problem. Additional corrective measures are included countered could be low power, poor sensitivity, distortion, limiter not in the Troubleshooting Procedure. Before starting with the Receiver operating properly, and low gain. By following the sequence of test Test Procedures, be sure the receiver is tuned and aligned to the proper

TEST EQUIPMENT REQUIRED

for test hookup shown:

- 1. Distortion Analyzer similar to: Heath #IM-12
- 2. Signal Generator similar to: Measurements #M-560
- 3. 6 db attenuation pad

The test equipment is hooked to the receiver as shown for all Receiver Test Procedures.



STEP 1

AUDIO POWER OUTPUT AND DISTORTION

TEST PROCEDURE

Measure Audio Power Output as follows:

- 1. Connect a 1.000-microvolt test signal modulated by 1,000 Hertz ±3.0 kHz deviation to the antenna jack.
- 2. Disconnect the W-BL-O Speaker Hi lead from LS 701-2. Hook up a 3.2 ohm load resistor from Speaker Hi to ground as shown.
- 3. Connect Distortion Analyzer input across the 3.2-ohm resistor.
- 4. For standard receivers set VOLUME Control for one-watt output (1.79 VRMS).

VOLTMETER SCALE ON DISTORTION ANALYZER

ONE WATT

5. Make distortion measurements according to manufacturer's instructions. Reading should be less than 10% (5% is typical).

SERVICE CHECK

If the distortion is more than 10%, or maximum audio output is less than one watt, make the following checks:

- 1. Battery and regulator voltage—low voltage will cause distortion. (Refer to the Receiver Schematic Diagram for voltages.)
- 2. Audio Bias Adjust (R367)—low current will cause distortion.
- 3. Audio Gain (Refer to Step 2A and 2B of Receiver Troubleshooting
- 4. Discriminator Alignment (Refer to Receiver Alignment on reverse side of page).

STEP 2

USABLE SENSITIVITY (12 db SINAD) TEST PROCEDURE

Measure sensitivity of the receiver modulated at the standard test modulation as follows:

- 1. Be sure Test Step 1 checks out properly.
- 2. Reduce the Signal Generator output from setting in TEST STEP 1.
- 3. Adjust Distortion Analyzer LEVEL control for a ± 2 db reading.
- 4. Set CONTROL for LEVEL to DISTORTION reading. Repeat Steps 1, 2, and 3 until difference in reading is 12 db (\pm 2 db to \pm 10 db).
- 5. The 12-db difference (Signal plus Noise And Distortion to noise plus distortion ratio) is the "usable" sensitivity level. Reading should be less than 0.3 microvolts with audio output at least ½ watt (1.25 volts RMS across the 3.2-ohm receiver load).

VOLTMETER SCALE ON **DISTORTION ANALYZER**



SERVICE CHECK

If the sensitivity level is more than 0.3 microvolts, make the following

- 1. Alignment of RF stages (Refer to RF Alignment in Receiver Alignment on reverse side of page).
- 2. Gain measurements as shown on the Receiver Troubleshooting Pro-

STEP 3

MODULATION ACCEPTANCE BAND-WIDTH (IF BANDWIDTH)

TEST PROCEDURE

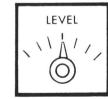
- 1. Be sure TEST STEPS 1 and 2 check out properly.
- 2. Set Signal Generator output for twice the microvolt reading obtained in TEST STEP 2 - 4.
- 3. Increase Signal Generator frequency deviation.
- 4. Adjust LEVEL Control for +2 db.

DB SCALE ON DISTORTION ANALYZER



5. Set CONTROL for LEVEL to DISTORTION reading. Repeat Steps 3, 4, and 5 until difference between readings becomes 12 db from +2 db to -10 db).

LEVEL DISTORTION ON DISTORTION ANALYZER



6. Deviation control reading for the 12-db difference is the Modulation Acceptance Bandwidth of the receiver. It should be more than - 6 kHz (typical value is ±9 kHz).

SERVICE CHECK

If the Modulation Acceptance Bandwidth test does not indicate the proper width, check the following:

- 1. Make gain measurements as shown on the Receiver Troubleshooting
- 2. Voltage reading of 2nd Limiter (Q308) should read 0.4 volts RMS with a one-microvolt input signal on Test Set Meter or 0.9 volts with voltmeter. (Measure at J312-3).
- 3. DO NOT RE-ALIGN factory adjusted filters (L308 through L315), unless positive evidence of a defective filter is ascertained. (Refer to Filter Alignment on the Receiver Alignment Procedure.)

FRONT END ALIGNMENT

These instructions are for tuning the oscillator and RF stages of the receiver and may be used when changing the receiver crystal or frequency. When necessary to realign the entire receiver, refer to the COMPLETE RECEIVER ALIGNMENT.

EQUIPMENT REQUIRED

- 1. G-E Test Set TM11 or TM12 (or 20,000 ohms-per-volt Multimeter).
- 2. A 130-174 mHz Signal Source. Keep signal level below saturation.

PRELIMINARY CHECKS AND ADJUSTMENTS

- Plug in the Test Set to the receiver centralized metering jack J312. Set Meter Polarity Switch on + and Meter Sensitivity Switch to 1. If using Multimeter, connect the negative lead to J312-13 (ground).
- Switch Test Set to Position "I" (or measure at J302 with Multimeter). Reading should be at least 12 volts.
- 3. Switch to Position "J" (or measure across R372 with Multimeter) and adjust Voltage Regulation Potentiometer R372 for a reading of 10 volts.
- 4. Turn SQUELCH control fully clockwise and VOLUME control to minimum. Switch to Position "G" (or measure at J312-9 with Multimeter) and adjust PA Bias Potentiometer R366 for a reading of 0.25 volt.

ALIGNMENT PROCEDURE

STEP	METERII 4EX3A10	NG POSITION Multimeter + at J312	TUNING CONTROL	METER READING	PROCEDURE
1.	D OSC	Pin 4	L425 (& L428 for two-fre- quency), L426 and L427	See Pro- cedure	Tune L425 (L428 for two-frequency) and L426 for maximum meter reading. Then tune L427 for minimum reading.
2.	C LIM-2	Pin 3	C302, C303 C309 & C310	Maxi- mum	Apply an on-frequency signal to J301 and tune C302, C303, C309 and C310 for maximum meter reading.
3.			C302 & C303	See Pro- cedure	While receiving a weak on- frequency signal at the Antenna, tune C302 and C303 for maximum quieting.
4.	A DISC	Pin 10	L425 & L428 (two- fre- quency only)	Zero	Apply an on-frequency signal to J701 and tune L425 (and L428 for two-frequency) for zero discriminator reading.

IMPROVED INTERMOD ADJUSTMENT

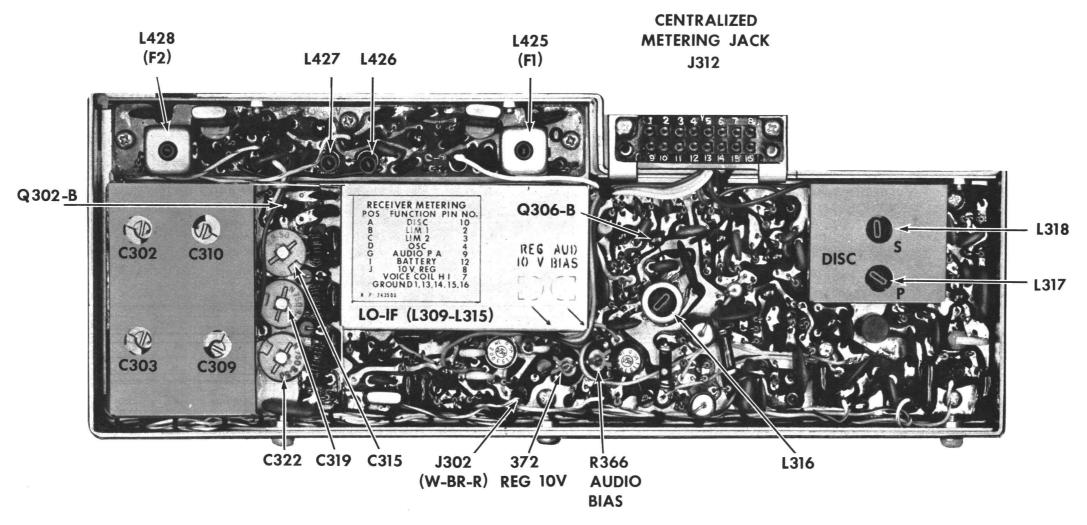
These instructions are for tuning the RF stages of a receiver that is equipped with the Improved Intermod Option. The receiver can be tuned for best sensitivity, or tuned to trade off sensitivity for improved intermodulation protection.

To Tune For Maximum Sensitivity:

- 1. Switch the GE Test Set to Position "C" (LIM-2).
- Apply a weak, on-frequency signal to the antenna jack and adjust C2351 for maximum meter reading. Then adjust C3302, C303, C309 and C310 for maximum meter reading. The 20 dB quieting sensitivity should be less than 0.8 microvolt.

To Trade Off Sensitivity For Improved Intermod Protection:

- 1. Switch the GE Test Set to Position "C" (LIM-2).
- 2. Apply a weak, on-frequency signal to the antenna jack and adjust C2351 towards minimum capacity in small steps. Adjust C302, C303, C309 and C310 for maximum meter reading each time C2351 is adjusted. Repeat this step until the desired sensitivity is obtained. The sensitivity can be adjusted for 0.8 to 1.5 microvolts.



COMPLETE RECEIVER ALIGNMENT

LBI-3757

EQUIPMENT REQUIRED

- 1. G-E Type Set TM11 or TM12 (or 20,000 ohms-per-volt Multimeter).
- 2. A 455 kHz, 10.7 mHz and 130-174 mHz Signal Source, Couple the 455 kHz signal through a small capacitor (approximately 100 pf). Couple the 10.7 mHz signal through a .01 μf capacitor for Hi IF, and through a 100 pf capacitor for Low IF adjustment. Keep signal levels below saturation.

PRELIMINARY CHECKS AND ADJUSTMI

- 1. Plug in the Test Set to the receiver centralized metering jack J312. Set Meter Polarity Switch on + and Meter Sensitivity Switch to TEST 1. If using Multimeter, connect the negative lead to J312-13 (ground).
- 2. Switch Test Set to Position "I" (or measure at J302 with Multimeter). Reading should be at least 12 volts.
- 3. Switch to Position "J" (or measure across R372 with Multimeter) and adjust Voltage Regulation Potentiometer R372 for a reading of
- 4. Turn SQUELCH Control fully clockwise and VOLUME control to minimum. Switch to Positive "G" (or measure at J312-9 with Multimeter) and adjust PA Bias Potentiometer R366 for a reading of 0.25 volt.

ALIGNMENT PROCEDURE

		POSITION	TUNING	METER		
STEP	4EX3A10	+ at J312	CONTROL	READING	PROCEDURE	
			1	DISCRIMINA	TOR	
1.	C LIM-2	Pin 3		0.3 volt (1.1 v with Multimeter)	Apply a 455 kHz signal to the base of Q306 and adjust signal level for 0.3 volt meter reading (to saturate limiters).	
2.	A DISC	Pin 10	L318	Zero	Apply a 455 kHz signal as above and adjust L318 (disc secondary) for zero meter reading.	
3.	A	Pin 10 .	L317 & L318	0.65 v (1.6 v with Multimeter)	Alternately apply a 445 kHz and 465 kHz signal while adjusting L317 and L318 for readings of at least 0.65 volt. Both readings should be within 10%.	
4.	B LIM-1	Pin 2	L316	Maximum	Apply a 455 kHz signal as above, and tune L316 for maximum meter reading.	
				OSCILLATOR ANI	MULTIPLIER	
5.	D OSC	Pin 4	IA25 (and IA28 for two-frequency), IA26 and IA27.	See Procedure	Tune L425 (L428 for two-frequency) and L426 for maximum meter reading. Then tune L427 for minimum reading.	
				HI IF		
6.	C LIM-2	Pin 3	C315, C319 and	Maximum	Apply a 10.7 kHz signal to the base of Q302 or an on-frequency signal to Antenna Jack J701. Tune C315, C319 and C322 for maximum meter reading.	
				LOW IF*		
7.	A DISC	Pin 10		Zero	Apply a 10.7 mHz signal to the base of Q304. Adjust the signal generator for discriminator zero.	
8.	C LIM-2	Pin 3	L308 thru L315	Maximum	Apply signal as above. Peak L308 through L315 for maximum meter reading, keeping signal below saturation.	
9.			L308 thru L315		Connect oscilloscope to Pin 2 and Pin 13 (Ground) of centralized metering jack J312. Modulate signal generator with at least ±30 kHz deviation with 60 Hertz (or less). Tune L308 through L315 for filter pattern as shown, keeping signal level below saturation. The above filter alignment should result in the center of the bandpass at 455 kHz ±1 kHz (±0.7 volt reading with meter in Position A), with an EIA modulation acceptance of ±6 to ±10 kHz.	
				RF		
10.	C LIM-2	Pin 3	C302, C303 C309 and C310	Maximum	Apply an on-frequency signal to J701 and tune C302, C303, C309 and C310 for maximum meter reading.	
11.			C302 and C303	See Procedure	While receiving a weak on-frequency signal at the Antenna, tune C302 and C303 for maximum quieting.	
				FREQUENCY AD	USTMENT	
12.	ADISC	Pin 10	L425 (and L428 for two-frequency)	Zero	Apply an on-frequency signal to J701 and tune L425 (and L428 for two-frequency) for zero discriminator reading. NOTE For proper frequency control of the receiver, it is	
			F F		For proper frequency control of the receiver, it is recommended that all frequency adjustments be made when the equipment is at a temperature of approxmately 75°F. In no case should frequency adjustments be made when the equipment is outside the temperature range of 50° to 90°F.	

ALIGNMENT PROCEDURE

132—174 MHZ RECEIVER TYPE ER-52-A

* NOTE — Low IF coils L308 through L315 have been set at the factory and will normally require no further adjustment. Do NOT realign the filter unless there is positive evidence of a defective filter. For location of IF coils, refer to the Receiver Service Sheet.

RC-1476C

RECEIVER TEST PROCEDURES

steps starting with Step 1, the defect can be quickly localized. Once operating frequency.

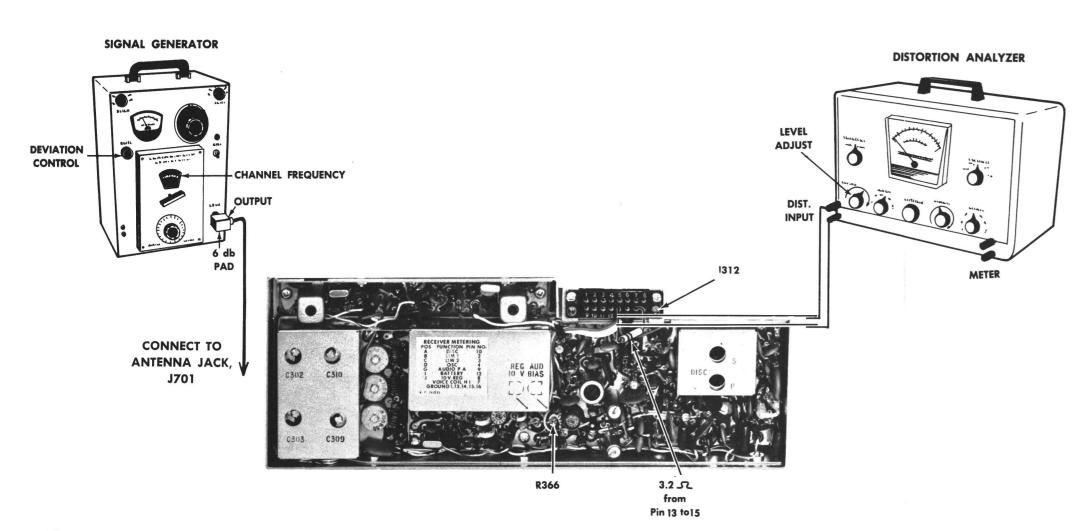
The Receiver Test Procedures are designed to help you to service the defective stage is pin-pointed, refer to the "Service Check" listed a receiver that is operating — but not properly. The problems en- to correct the problem. Additional corrective measures are included countered could be low power, poor sensitivity, distortion, limiter not in the Troubleshooting Procedure Before starting with the Receiver operating properly, and low gain. By following the sequence of test Test Procedures, be sure the receiver is tuned and aligned to the proper

TEST EQUIPMENT REQUIRED

for test hookup shown:

- 1. Distortion Analyzer similar to: Heath #IM-12
- 2. Signal Generator similar to: Measurements #M-560
- 3. 6 db attenuation pad

The test equipment is hooked to the receiver as shown for all Receiver Test Procedures.



STEP 1

AUDIO POWER OUTPUT AND DISTORTION

TEST PROCEDURE

Measure Audio Power Output as follows:

- 1. Connect a 1,000-microvolt test signal modulated by 1,000 Hertz ±3.0 kHz deviation to the antenna jack.
- 2. Disconnect the W-BL-O Speaker Hi lead from LS 701-2. Hook up a 3.2 ohm load resistor from Speaker Hi to ground as shown.
- 3. Connect Distortion Analyzer input across the 3.2-ohm resistor.
- 4. For standard receivers set VOLUME Control for one-watt output (1.79 VRMS).

VOLTMETER SCALE ON DISTORTION ANALYZER



ONE WATT

5. Make distortion measurements according to manufacturer's instructions. Reading should be less than 10% (5% is typical).

SERVICE CHECK

If the distortion is more than 10%, or maximum audio output is less than one watt, make the following checks:

- 1. Battery and regulator voltage—low voltage will cause distortion. (Refer to Receiver Schematic Diagram for voltages.)
- 2. Audio Bias Adjust (R366)—low current will cause distortion.
- 3. Audio Gain (Refer to Step 2A and 2B of Receiver Troubleshooting
- 4. Discriminator Alignment (Refer to Receiver Alignment on reverse side of page).

STEP 2

USABLE SENSITIVITY (12 db SINAD) TEST PROCEDURE

Measure sensitivity of the receiver modulated at the standard test modulation as follows:

- 1. Be sure Test Step 1 checks out properly.
- 2. Reduce the Signal Generator output from setting in TEST STEP 1.
- 3. Adjust Distortion Analyzer LEVEL control for a +2 db reading.
- 4. Set CONTROL for LEVEL to DISTORTION reading. Repeat Steps 1, 2, and 3 until difference in reading is 12 db (+2 db to -10 db).
- 5. The 12-db difference (Signal plus Noise And Distortion to noise plus distortion ratio) is the "usable" sensitivity level. Reading should be less than 0.3 microvolts with audio output at least ½ watt (1.25 volts RMS across the 3.2-ohm receiver load).

VOLTMETER SCALE ON DISTORTION ANALYZER



SERVICE CHECK

If the sensitivity level is more than 0.3 microvolts, make the following

- 1. Alignment of RF stages (Refer to RF Alignment in Receiver Alignment on reverse side of page)
- 2. Gain measurements as shown on the Receiver Troubleshooting Pro-

STEP 3

MODULATION ACCEPTANCE BAND-WIDTH (IF BANDWIDTH)

TEST PROCEDURE

- 1. Be sure TEST STEPS 1 and 2 check out properly.
- 2. Set Signal Generator output for twice the microvolt reading obtained in TEST STEP 2 - 4.
- 3. Increase Signal Generator frequency deviation.
- 4. Adjust LEVEL Control for +2 db.

DB SCALE ON DISTORTION ANALYZER



5. Set CONTROL for LEVEL to DISTORTION reading. Repeat Steps 3, 4, and 5 until difference between readings becomes 12 db from +2 db to -10 db).

LEVEL DISTORTION ON DISTORTION ANALYZER

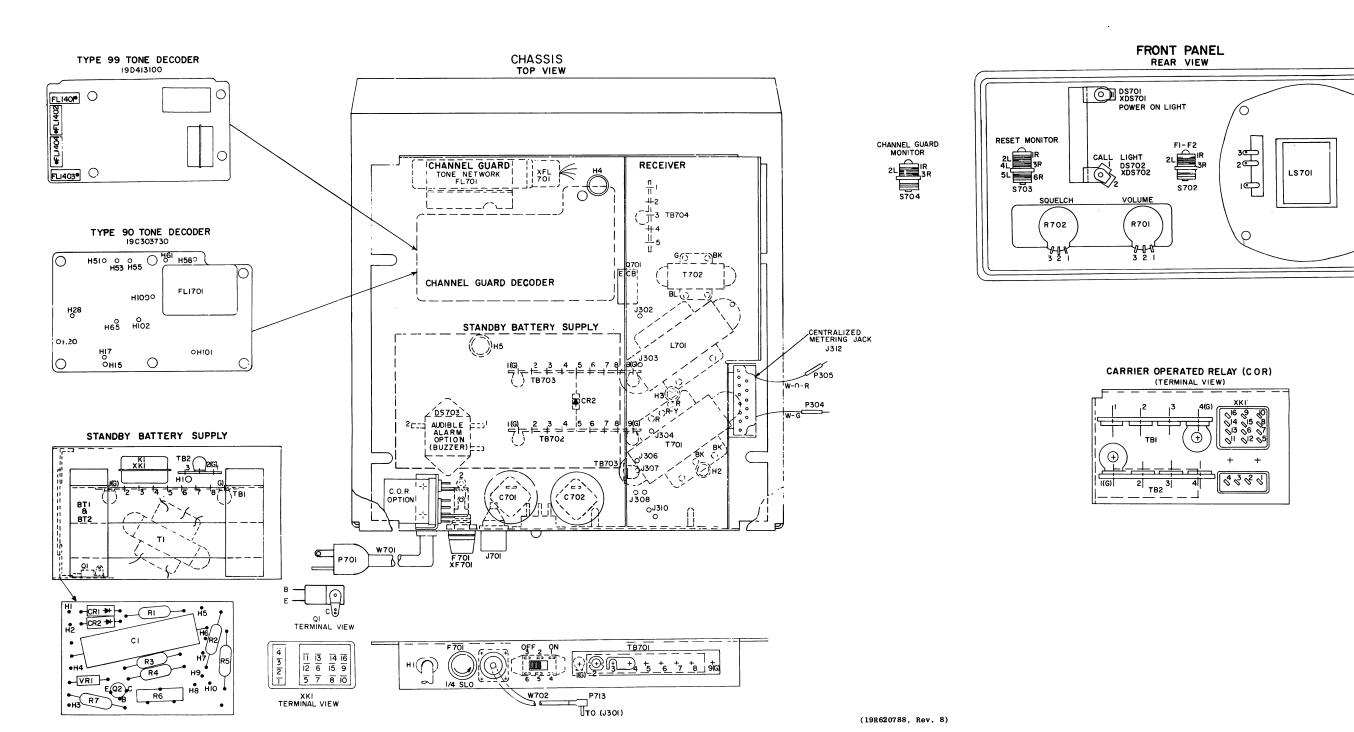


6. Deviation control reading for the 12-db difference is the Modulation Acceptance Bandwidth of the receiver. It should be more than \pm 6 kHz (typical value is \pm 9 kHz).

SERVICE CHECK

If the Modulation Acceptance Bandwidth test does not indicate the proper width, check the following:

- 1. Make gain measurements as shown on the Receiver Troubleshooting
- 2. Voltage reading of 2nd Limiter (Q308) should read 0.4 volts RMS with a one-microvolt input signal on Test Set Meter or 0.9 volts with voltmeter. (Measure at J312-3).
- 3. DO NOT RE-ALIGN factory adjusted filters (L308 through L315), unless positive evidence of a defective filter is ascertained. (Refer to Filter Alignment on the Receiver Alignment Procedure.)



OUTLINE DIAGRAMS

MONITOR RECEIVER CHASSIS AND FRONT PANEL

(19C317160, Rev. 3)

CARRIER OPERATED RELAY

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S70I-5 € N22 - TBI-7

MONITOR RECEIVER CHASSIS AND FRONT PANEL RC-1478E

SCHEMATIC DIAGRAM

13

LBI-3757

PARTS LIST

LBI-3754H

MONITOR RECEIVER MAIN CHASSIS 19C311011G1 FRONT PANEL ASSEMBLY 19D402678G1

MDL-1/4.	SYMBOL	GE PART NO.	DESCRIPTION
Table Tabl			
Sim to PR Mallory WP-068.			
CR701 and CR702 F701 7487942P1 Silicon. F701 7487942P1 Slow blowing: 1/4 amp at 250 v; sim to Bussman MDL-1/4. L701 19A115671P1 Reactor: 0.21 h min, 7.5 ohms DC res max, 20 VDC operating. F701 (Part of W701). F702 4029840P2 Connector: female contact; sim to AMP 42827-2. F703 7147199P2 Electronics 21804. F704 4029840P2 Connector: female contact; sim to Winchester Electronics 21804. F705 (Part of W702). F706 (Part of W702). F707 (Part of W702). F708 (Part of W702). F709 (Part of W702). F709 (Part of W702). F700 (Part of W702). F701 19A116118P1 Silicon, NPN. Earlier than REV B: Silicon, NPN. Earlier than REV B: Silicon, NPN. F706 Stayson Silicon: 68 ohms il0%, 1 w. F707 (Part of W702) Wirewound: 130 ohms i5%, 5 w; sim to Hamilton Hall Type HR. F708 (Part of W702) Silicon: 68 ohms il0%, 2 w; sim to IRC Type in the stay of the st	and	7476442P20	Electrolytic: 1600 µf +250% -10%, 50 VDCW; sim to PR Mallory WP-068.
### Troin		ı	DIODES AND RECTIFIERS
Troin Target Troin Tro	and	4037822P1	Silicon.
MDL-1/4.		-	
Reactor: 0.21 h min, 7.5 ohms DC res max, 20 VDC operating.	F701	7487942P1	Slow blowing: 1/4 amp at 250 v; sim to Bussmann MDL-1/4.
20 VDC operating.			
P701	L701	19A115671P1	Reactor: 0.21 h min, 7.5 ohms DC res max, 20 VDC operating.
P702 and P703			
### And P703 P704 P705 P706 P706 P706 P706 P706 P706 P706 P706 P706 P707 P			
Electronics 21804. P706 thru P710 P713 (Part of W702).	and	4029840P2	Contact, electrical: sim to AMP 42827-2.
### P710 ### P7	and	7147199P2	Connector: female contact; sim to Winchester Electronics 21804.
19A116118P1 Silicon, NPN.	thru	4029840P2	Contact, electrical: sim to AMP 42827-2.
Q701*	P713		(Part of W702).
Earlier than REV B: Silicon, NPN.			
19A115527P1 Silicon, NPN.	Q701*	19A116118P1	1
Composition: 68 ohms ±10%, 1 w.		10411550571	
R703 3R78P680K Composition: 68 ohms ±10%, 1 w.		19411552721	Silicon, NPN.
### R704 thru R706 Wirewound: 130 ohms ±5%, 5 w; sim to Hamilton Hall Type HR. #### R707			
### ### ### ### ### ### ### ### ### ##			
Troing T	thru	5493035P22	Wirewound: 130 ohms ±5%, 5 w; sim to Hamilton Hall Type HR.
S701 T145098P1 Slide: DPDT, 0.75 amp at 125 VAC or 0.5 amp at 125 VDC; sim to Stackpole SS-150.	R707	19B209022P115	Wirewound: 1 ohm ±10%, 2 w; sim to IRC Type BWH
T701 19B209074P1 Power, step-down: single phase, Pri: 117 v, 50/60 Hz, Sec 1: 850 ma at 13.8 VDC. T702 19B209079P1 Audio freq: 0.3-3 KHz freq range, Pri: 55 ohms ±10% imp, 0.895 ohm ±10% DC res Sec: 3.2 ohms imp, 0.168 ohm DC res. T8701 7117710P7 Phen: 7 terminals; sim to Cinch 1770. T8702 7775500P119 Phen: 9 terminals.			SWITCHES
T701 19B209074P1 Power, step-down: single phase, Pri: 117 v, 50/60 Hz, Sec 1: 850 ma at 13.8 VDC. T702 19B209079P1 Audio freq: 0.3-3 KHz freq range, Pri: 55 ohms ±10% imp, 0.895 ohm ±10% DC res Sec: 3.2 ohms imp, 0.168 ohm DC res. TB701 7117710P7 Phen: 7 terminals; sim to Cinch 1770. TB702 7775500P119 Phen: 9 terminals.	S701	7145098Pl	Slide: DPDT, 0.75 amp at 125 VAC or 0.5 amp at 125 VDC; sim to Stackpole SS-150.
T702 19B209079P1 Audio freq: 0.3-3 KHz freq range, Pri: 55 ohms ±10% imp, 0.895 ohm ±10% DC res Sec: 3.2 ohms imp, 0.168 ohm DC res.			
Sec: 3.2 ohms imp, 0.168 ohm DC res. TERMINAL BOARDS TB701 7117710P7 Phen: 7 terminals; sim to Cinch 1770. TB702 7775500P119 Phen: 9 terminals.	T701	19B209074P1	Power, step-down: single phase, Pri: 117 v, 50/60 Hz, Sec 1: 850 ma at 13.8 VDC.
TB701 7117710P7 Phen: 7 terminals; sim to Cinch 1770. TB702 7775500P119 Phen: 9 terminals.	T702	19B209079P1	Audio freq: 0.3-3 KHz freq range, Pri: 55 ohms ±10% imp, 0.895 ohm ±10% DC res, Sec: 3.2 ohms imp, 0.168 ohm DC res.
TB702 7775500P119 Phen: 9 terminals.			TERM INAL BOARDS
	TB701	7117710P7	
TB703	and	7775500P119	Phen: 9 terminals.
TB704 7775500Pl1 Phen: 5 terminals.	TB704	7775500P11	Phen: 5 terminals.

	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
	ТВ706	7775500P44	Phen: 2 terminals.			2 FREQUENCY SWITCH KIT 19A122310G1			TRANSFORMERS	TB1	7775500P26	Phen: 10 terminals.
							Т1	19B209017P1	Power: single phase, Pri: 117 v, 50/60 Hz, Sec 1: 25/25 v.	TB2	7775500P6	Phen: 4 terminals.
	W701*	19A116740P2	Power: approx 8 feet long, 2 poles, 3 wire grounding; sim to Belden 17239.	P711 and	4029840P2	Contact, electrical: sim to AMP 42827-2.			TERM INAL BOARDS		:	
		4036441P1	In REV B and earlier:	P712			тві	7775500P119	Phen: 9 terminals.	XK1	5491595P5	Relay: 16 contacts; sim to Allied Control 30054-2.
		403644191	Power: approx 6 feet long, with 2-contact plug (P701); sim to GE 2071-1.			SWITCHES	TB2	7775500P7	Phen: 3 terminals.			30034-2.
	₩702	:	CABLE 19A122691G1	8702	19P209139P4	Lever: 3 amps at 120 VAC, Position down: 1 form C contact, locking; sim to Switchcraft 28203L.	XK1	5491595P5	Relay: 16 contacts; sim to Allied Control			IMPROVED INTERMODULATION 19A127250G1
	J701	4029493P1	JACKS AND RECEPTACLES Receptacle, coaxial: sim to Amphenol 83-798 or			HARDWARE KIT (CHANNEL GUARD) 19A122322G1			30054-2.			
';			Equiv. Military S0-239A.	1					STAND-BY POWER SUPPLY BOARD 19B216567G1	C2351	5491271P103	Variable, sub-miniature: approx 1.7-8.3 pf, 750 v peak; sim to EF Johnson 189.
				\$704	19A122310G2				CAPACITORS			MISCELLANEOUS
	P713	5496078P6	Right angle: coaxial; sim to FXR 27-6.		19B209139P4	Lever: 3 amps at 120 VAC,	C1	19A115680P12	Electrolytic: 100 µf +150% -10%, 30 VDCW; sim		19A122161G2	Top cover.
1			MISCELLANEOUS			Position down: 1 form C contact, locking; sim to Switchcraft 28203L.			to Mallory Type TTX.		19A116768P8	Bushing, strain relief: cable; sim to Heyco SR-5P-4. (Used with W701 in 19C311011G1).
		19B209044P11	RF: approx 15 inches long; sim to Amphenol 21-598.			CABLE ASSEMBLY 19B205451G1 (TYPE 99 TONE DECODER)			DIODES AND RECTIFIERS		19B205512G1	Casting. (Used in 19D402678G1).
ssmann						19B205451G2 (TYPE 99 TONE DECODER)	CR1 and CR2	4037822P1	Silicon.		19C303769P1	Grille, (Used in 19D402678G1),
	XF701	19B209005P1	Fuseholder, post type, phen: 15 amps at 250 v; sim to Littelfuse 342012.								N529P17D	Button plug: approx 15/32 inch dia. (Used in 19D402678G1).
				Pl thru	4036634P1	Contact, electrical: sim to AMP 42428-2.	Q2	19A115362P1	Silicon, NPN; sim to Type 2N2925.		19A122240P1	Support. (Used with XDS701 in 19D402678G1).
			FRONT PANEL ASSEMBLY 19D402678G1	P13		RESISTORS					4037559P9 19C307038P6	Bumper, rubber. (Used in 19D402678G1). Nut, push-on. (Holds jewel in 19D402678G1).
			INDICATING DEVICES	R708	5493035P10	Wirewound: 3.5 ohms ±5%, 5 w; sim to Tru-Ohm	Rl	3R77P470J	Composition: 47 ohms ±5%, 1/2 w.		19B204949P3	Jewel: amber. (Used in 19D402678G1).
	DS701	19C307037P19	Lamp, incandescent: 14 v; sim to GE 756.			Type X-60.	R2	3R77P330J	Composition: 33 ohms ±5%, 1/2 w. Composition: 8200 ohms ±5%, 1/2 w.		19A122210P1	Lens, green. (Used with XDS702 in 19D402678G1).
							R3 and R4	3R77P822J	Composition: 6200 Gimes 10%, 1/2 w.		19A115679P1	Knob, push-on: black. (Used with R702, 703 in 19D402678G1).
ster	LS701	19B209101P1	Permanent magnet, 5-inch: 2-1/4 w operating, paper dust cap; sim to Cletron X10271.	TB705	7775500P8	Phen: 4 terminals.	R5	3R77P622J	Composition: 6200 ohms ±5%, 1/2 w.		NP248990	Nameplate, (Used in 19D402678G1).
						CABLE ASSEMBLY 19B205450G1 (CHANNEL GUARD)	R6	19B209358P103	Variable, carbon film: approx 50 to 1000 ohms ±10%, 0.2 w; sim to CTS Type X-201.		5491595P9	Retainer, spring. (Used with Kl in 19B205435G2 and in 19C303533G3).
	P701	4036634P1	Contact, electrical; sim to AMP 42428-2.			19B205450G2 (CHANNEL GUARD AND TONE DECODER)	R7	3R77P472J	Composition: 4700 ohms ±5%, 1/2 w.		19A115222P3	Washer, shield. (Used with Q701).
			RESISTORS	P1	4029840P2	Contact, electrical: sim to AMP 42827-2.			VOLTAGE REGULATORS		19A116023P1 19A127515G1	Insulator, plate. (Used with Q701). Terminal board. (Used with Q701).
	R701	5496870Pll	Variable, carbon film: 5000 ohms ±20%, 0.25 w;	thru P3	102501072	contact, electrical. Sim to Amp 42021-2.	VR1	4036887P6	Silicon, Zener.		19812731331	Terminal board, (osed with 402).
	R702	5496870P15	sim to Mallory LC(5K). Variable, carbon film: 5000 ohms ±20%, 0.5 w;			SOCKETS			CARRIER OPERATED RELAY			
			sim to Mallory LC(5K).	XFL701	7768887P17	Tube, phen: 7 pins; sim to Elco 04-710-02.			19C3O3533G3			
	R709	3R77P150K	Composition: 15 ohms ±10%, 1/2 w.			BATTERY KIT 19A122315G2			CAPACITORS			
	XDS701	19B209342P1	Lampholden, circle Leaguett 7 04 1			(Used with 19B205435G2).	C1	19A116080P7	Polyester: 0.1 µf ±20%, 50 VDCW.			
ilton	ADSTO	19820934221	Lampholder: sim to Leecraft 7-04-1.			DIODES AND RECTIFIERS	C3	19A116080P7	Polyester: 0.1 µf ±20%, 50 VDCW.			
			FRONT PANEL KIT 19A122311G1	CR2	4037822P1	Silicon.			DIODES AND RECTIFIERS			
ype BWH.			INDICATING DEVICES			STAND-BY POWER SUPPLY 19B205435G2	CR1 CR2	5494922P1 19A115250P1	Silicon; sim to Type 1N456. Silicon.			
	DS702	19C307037P19	Lamp, incandescent: 14 v; sim to GE 756.			(Used with 19A122315G2)			RELAYS			
amp at			SWITCHES	-	10000100700	BATTERIES	K1	5491595P14	Armature: 1.5 w max operating, 520 ohms ±15%			
	8703	19B209139P5	Lever: 3 amps at 120 VAC, Position up: 1 form B contact, momentary,	BT1 and BT2	19B201887P2	Storage, nickel-cadmium: 6 v min; sim to GE 41B001AAQ1.			coil res, 4 form C contacts rated at 0.5 amp at 12 VDC; sim to Allied Control T154-X-131.			
		·	Position down: 1 form A, 1 form B contacts, locking; sim to Switchcraft 28000 (Pt. 205-1007).			RELAYS			TRANSISTORS			
			SOCKETS	К1	5491595P14	Armature: 1.5 w operating, 520 ohms ±15% coil res, 4 form C contacts; sim to Allied Control	Q1	19A115123P1	Silicon, NPN.			
res,	XDS702	19B209342P1	Lampholder: sim to Leecraft 7-04.			T154-X-131.	Q2	19A115706P1	Silicon, PNP; sim to Type 2N3638.			
			EXTERNAL ALARM KIT									
			19A122312G1	Q1	19A116118P1	Silicon, NPN.	R2 R4	3R77P242J 3R77P203J	Composition: 2400 ohms ±5%, 1/2 w. Composition: 20,000 ohms ±5%, 1/2 w.			
	DS703	19B200788P3	Buzzer: 12 VDC or 12-16 VAC nominal, 200 ma DC		1000000000122	Windows and 2 2 character to Tage Type	R5	3R77P512J	Composition: 5100 ohms ±5%, 1/2 w.			
	1000	198200786F3	operating; sim to Line Electric BD-1. (Used with second relay, GE Dwg 19C300957P2).	R2	19B209022P123	Wirewound: 2.2 ohms ±10%, 2 w; sim to IRC Type BWH.						
											!	

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for description of parts affected by these revisions.

- REV. A (19C311011-G1 only) To change antenna connector from phono to UHF Type. Changed W702.
- REV. A (19D402678-Gl only) To make minimum volume level consistent with requirements of tone decoders and to change the ground circuit for indicator lamp DS701. Changed R709 and XDS701.
- REV. B (19C311011-G1 only)
 To incorporate a different audio transistor. Changed Q701.
- REV. C To incorporate a 3-wire power cable. Changed W701.

PARTS LIST

LBI-3758D

25 - 50 MHz RECEIVER TYPE ER-51-A

RECEIVER BOARD 19D402429G1 THRU G3

SYMBOL	GE PART NO.	DESCRIPTION	
		RECEIVER BOARDS 25-33 MHz Board 19D402429G1 33-42 MHz Board 19D402429G2 42-50 MHz Board 19D402429G3	
C301	5490008P24		
C302	5490008P19	Motive Type DM-15. Silver mica: 47 pf ±5%, 500 VDCW; sim to Electro	
C303	5490008P13	Motive Type DM-15. Silver mica: 27 pf ±5%, 500 VDCW; sim to Electro	
C304	7130348P4	Motive Type DM-15.	
C305	5490008P24	Molded: 2.2 pf ±0.11 pf, 500 VDCW, temp coef approx 0 PPM; sim to Jeffers Type JM-5/32.	
		Silver mica: 75 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
C306	5490008P19	Silver mica: 47 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
C307	5490008P13	Silver mica: 27 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
C308	7491827P2	Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague 19C180.	
C309	5494481P115	Ceramic disc: 3000 pf ±20%, 500 VDCW; sim to RMC Type JF Discap.	
C310	7491827P2	Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague Type 19C180.	
C311	5490008P24	Silver mica: 75 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
C312	5490008P19	Silver mica: 47 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
C313	5490008P13	Silver mica: 27 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
C314	7130348P3	Molded, phen: 1 pf ±.05 pf, 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32.	
C315	5490008P21	Silver mica: 56 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
C316	5490008P17	Silver mica: 39 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
C317	5490008P11	Silver mica: 22 pf ±5%, 500 VDCW; sim to Electro	
C318	7491827P2	Motive Type DM-15. Ceramic disc: .01 \(\mu f + 80\% - 30\%, 50 \) VDCW; sim to	
C319	5490008P21	Sprague Type 19C180. Silver mica: 56 pf ±5%, 500 VDCW; sim to Electro	
C320	5490008P17	Motive Type DM-15. Silver mica: 39 pf ±5%, 500 VDCW; sim to Electro	
C321	5490008P13	Motive Type DM-15. Silver mica: 27 pf ±5%, 500 VDCW; sim to Electro	
C322	5494481P115	Motive Type DM-15. Ceramic disc: 3000 pf ±20%, 500 VDCW; sim to	
C323	19A116080P7	RMC Type JF Discap. Polyester: 0.1 µf ±20%, 50 VDCW.	
C324	7491827P2	Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague Type 19C180.	
C325*	5491870P140J	Mica: 140 pf ±5%, 300 VDCW; sim to Electro	
		Motive Type DM-15. Earlier than REV H in G1;	
	5490008P29	Earlier than REV G in G2, G3: Silver mica: 120 pf ±5%, 500 VDCW; sim to	
C326	5490446Pl	Electro Motive Type DM-15. Variable, ceramic: approx 8-50 pf, 350 YDCW,	
	7130348P1	temp coef -750 PPM; sim to Erie Style 557-36. Molded: 0.47 pf ±.047 pf, 500 VDCW, temp coef	
C327	1130340F1	approx 0 PPM; sim to Jeffers Type JM-5/32.	

	SYMBOL	GE PART NO.	DESCRIPTION
	C328	5490446P1	Variable, ceramic: approx 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie Style 557-36.
-	C329*	5491870P140J	Mica: 140 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.
1			Earlier than REV H in Gl: Earlier than REV G in G2, G3:
1		5490008P29	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
Н	C330	7130348P1	Molded: 0.47 pf ±.047 pf, 500 VDCW, temp coef approx 0 PPM; sim to Jeffers Type JM-5/32.
$\ \ $	C331*	5491870P140J	Mica: 140 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.
			Earlier than REV H in Gl: Earlier than REV G in G2, G3:
$\ \ $		5490008P29	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
Ш	C332	5490446P1	Variable, ceramic: approx 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie Style 557-36.
$\ \ $	C333*	5494481P9	Ceramic disc: 680 pf ±20%, 500 VDCW; sim to RMC Type JF Discap.
$\ \ $			In 19D402429Gl of REV R and earlier: In 19D402429G2, G3 of REV P and earlier:
$\ \ $		5494481P115	Ceramic disc: 3000 pf ±20%, 500 VDCW; sim to RMC
	C334*	19A116080P1	Type JF Discap. Polyester: .01 µf ±20%, 50 VDCW.
			In G1 REV D and earlier: In G2 and G3 REV C and earlier:
$\ \ $		7491827P2	Ceramic disc: .01 μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180.
	C335 and C336	19A116080P107	Polyester: 0.1 µf ±20%, 50 VDCW.
	C337	5490008P33	Silver mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
	C338*	19A116080P1	Polyester: .01 µf ±20%, 50 VDCW.
			In G1 REV D and earlier: In G2 and G3 REV C and earlier:
		7491827P2	Ceramic disc: .01 μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180.
	C339 and C340	5490008P35	Silver mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
	C341	7130348P9	Molded: 0.22 pf ±.022 pf, 500 VDCW, temp coef approx 0 PPM; sim to Jeffers Type JM-5/32.
	C342	5496219P41	Ceramic disc: 10 pf ±5%, 500 VDCW, temp coef 0 PPM.
	C343	19A116656P180J1	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -150 PPM.
	C344	5496219P41	Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.
	C345	19Al16656Pl80J1	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -150 PPM.
	C346	5496219P41	Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.
	C347	19A116656P180J1	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -150 PPM.
	C348	5496219P41	Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.
	C349	19A116656P180J1	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef
	C350	5496219P41	-150 PPM. Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp
	C351	19A116656P180J1	coef 0 PPM. Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef
	C352	5496219P41	-150 PPM. Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp
	C353	19A116656P180J1	coef 0 PPM. Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef
	C354	5496219P41	-150 PPM. Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp
	C355*	7489162P35	coef 0 PPM. Silver mica: 220 pf ±5%, 500 VDCW; sim to
			Electro Motive Type DM-15. In 19D402429Gl of REV L and earlier:
		19A116656P180J1	In 19D402429G2, G3 of REV K and earlier: Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef
			-150 PPM.

	SYMBOL	GE PART NO.	DESCRIPTION
	C356*	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
			In 19D402429Gl of REV L and earlier: In 19D402429G2, G3 of REV K and earlier:
		7491930P3	Polyester: .0047 µf ±20%, 100 VDCW; sim to
	C357*	19A116080P3	GE Type 61F. Polyester: 0.022 µf ±20%, 50 VDCW,
			Earlier than REV H in Gl: Earlier than REV G in G2, G3:
		5492638P101	Ceramic disc: 0.1 \(\mu f + 100\% - 0\%, \) VDCW; sim to Sprague Type 54C23.
	C358	5494481P112	Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC
	C359	5496219P367	Type JF. Ceramic disc: 150 pf ±5%, 500 VDCW, temp coef
	C360*	19A116080P3	-150 PPM. Polyester: 0.022 µf ±20%, 50 VDCW,
			Earlier than REV H in Gl: Earlier than REV G in G2, G3:
		5492638P101	Ceramic disc: 0.1 µf +100% -0%, 3 VDCW; sim to
	C361	5494481P112	Sprague Type 54C23. Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to
С	C362*	19A116080P3	RMC Type JF Discap. Polyester: 0.022 µf ±20%, 50 VDCW.
			Earlier than REV H in Gl: Earlier than REV G in G2, G3:
		5492638P101	Ceramic disc: 0.1 µf +100% -0%, 3 VDCW; sim to
·	C363	7491393P1	Sprague Type 54C23. Ceramic disc: .001 \(\mu f + 100\% - 0\% , 500 \) \(\mu DCW; \) sim
	C364	5494481P112	to Sprague Type 1219C4. Ceramic disc: 1000 pf ±10%. 500 VDCW: sim to RMC
	C365*	19A116080P3	Type JF Discap. Polyester: 0.022 µf ±20%, 50 VDCW.
			Earlier than REV H in Gl:
		5492638P101	Earlier than REV G in G2, G3: Ceramic disc: 0.1 µf +100% -0%, 3 VDCW; sim to
	C366	7491393P1	sprague Type 54C23. Ceramic disc: .001 µf +100% -0%, 500 VDCW; sim
	C367	5494481P112	to Sprague Type 1219C4. Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to
	C368*	19A116080P1	RMC Type JF Discap. Polyester: .01 µf ±20%, 50 VDCW.
			In Gl REV C or earlier: In G2 and G3 REV B or earlier:
		7491827P2	Ceramic disc: .01 µf +80% -30%, 50 VDCW: sim to
	C369	19A116656P18OJ1	Sprague Type 19C180. Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef
ef	C370	19A116080P107	-150 PPM. Polyester: 0.1 µf ±10%, 50 VDCW.
	C371 and	5490008P37	Silver mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
	C372	1041150000000	1
	C373 C374	19A116080P107 5494481P111	Polyester: 0.1 µf ±10%, 50 VDCW. Ceramic disc: 1000 pf ±20%, 500 VDCW; sim to RMC
	and C375		Type JF,
	C376 C377*	19A116080P109 5494481P11	Polyester: 0.22 µf ±10%, 50 VDCW. Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to
			RMC Type JF Discap.
		54044017107	Earlier than REV G in G1: Earlier than REV F in G2, G3:
	9950	5494481P107	Ceramic disc: 470 pf ±20%, 500 VDCW; sim to RMC Type JF Discap.
	C378 C379*	19A116080P5 19A116080P109	Polyester: .047 µf ±20%, 50 VDCW. Polyester: 0.22 µf ±10%, 50 VDCW.
		-	Earlier than REV A:
		5492638P107	Ceramic disc: 0.1 µf +80% -20%, 12 VDCW; sim to Sprague 20C202.
ا ل			(Con't. on page 18)

F2

W-Y-R

OSC. METERING

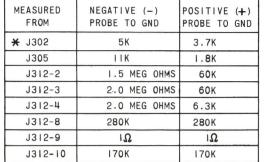
RUNS ON BOTH SIDES

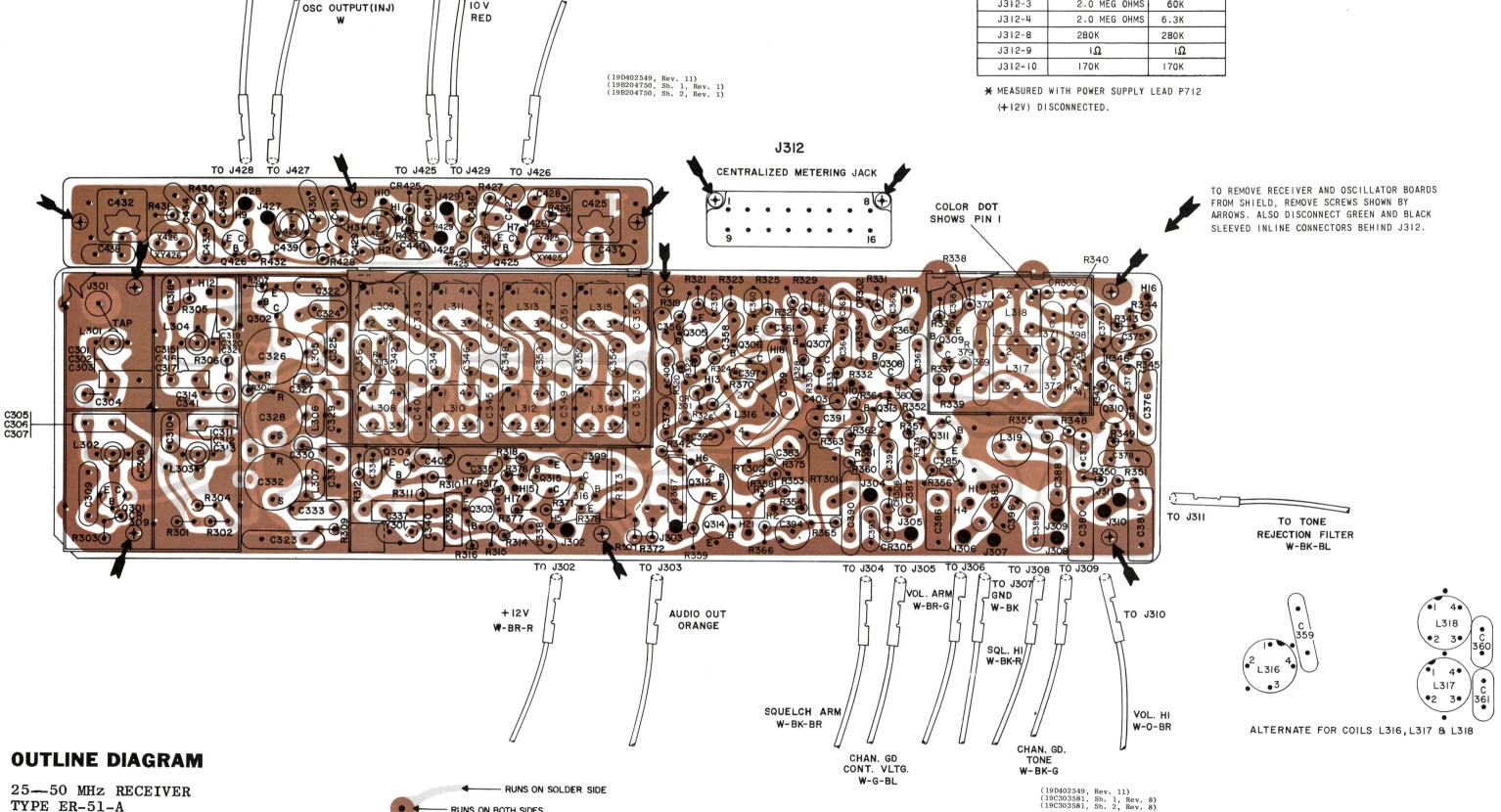
- RUNS ON COMPONENT SIDE

W-Y-BR



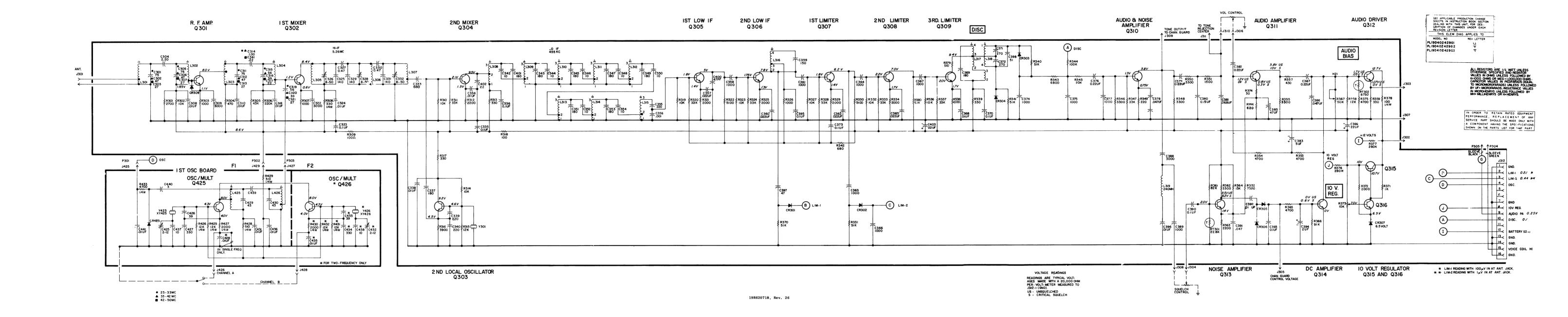
RESISTANCE READINGS ARE TYPICAL READINGS MEASURED TO J312-13 (GROUND), AND WITH ALL POWER REMOVED FROM THE CHASSIS.





25-50 MHz RECEIVER TYPE ER-51-A

RC-1479E



SCHEMATIC DIAGRAM

25—50 MHz RECEIVER TYPE ER-51-A

19R620718, Rev. 26

LBI-3	GE PART NO.	(LBI-3758 Con't. from page 15) DESCRIPTION	SYMBOL	GE PART NO	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART N	D. DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	PRODUCTION CHANGES Changes in the equipment to improve performance or to simplify circuits a
STWIDGE	GE TAILT INC.					-			1	 		1	1					identified by a "Revision Leter", which is stamped after the model number the unit. The revision stamped on the unit includes all previous revisio Refer to the Parts List for descriptions of parts affected by these revis
C380*	19A116080P8	Polyester: 0.15 µf ±20%, 50 VDCW.	CR309*	4038642P1	Germanium. Added in G1 by REV D. Added in G2	Q310*	19A116774P1	Silicon, NPN; sim to Type 2N5210.	R324	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.	R365	3R77P472K	Composition: 4700 ohms ±10%, 1/2 w.	C437 and C438	5490008P6	Silver mica: 10 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	
		Earlier than REV A:			and G3 by REV C.			In 19D402429G1 REV N and P: In 19D402429G2, REV M and N:	R325	3R77P202J	Composition: 2000 ohms ±5%, 1/2 w.	R366*	3R77P913J	Composition: 91,000 ohms ±5%, 1/2 w.	C439	7130348P3	Molded: 1 pf ±.05 pf, 500 VDCW, temp coef approx	REV. A - (25-50 MHz Receiver Boards 19D402429-G1, 2 and 3)
	19B209243P7	Polyester: 0.1 µf ±20%, 50 VDCW.		İ	JACKS AND RECEPTACLES		19A116755P1	Silicon, NPN; sim to Type 2N3947.	R326 R327	3R77P102K 3R77P103K	Composition: 1000 ohms ±10%, 1/2 w. Composition: 10,000 ohms ±10%, 1/2 w.			In 19D402429G1 of REV S and earlier: In 19D402429G2, G3 of REV R and earlier:	""	110001010	0 PPM; sim to Jeffers Type JM-5/32.	To improve audio response. C379, C380 C386, R355 and R356 were changed. C384 was deleted.
81*	19A116080P106	Polyester: 0.068 µf ±10%, 50 VDCW.	J301	5496078P3	Receptacle, push-on: sim to FXR 27-3.		1	In 19D402429Gl of REV M and earlier:	R327	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.		3R77P243J	Composition: 24,000 ohms ±5%, 1/2 w.	C440	5496218P34	Ceramic disc: 3 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	REV. B - (25-33 MHz Receiver Board 19D402429-G1 Only)
		In 19D402429Gl of REV N and earlier: In 19D402429G2, G3 of REV M and earlier:	J302 thru	4033513P4	Pin, contact: sim to Bead Chain L93-3.			In 19D402429G2, G3 of REV L and earlier:	R329	3R77P202J	Composition: 2000 ohms ±5%, 1/2 w.	R367*	19B209358P108	Variable, carbon film: approx 2000 to 50,000 ohms ±10%, 0.25 w; sim to CTS Type X-201.	C441	7491827P2	Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	To improve tuning of front end and oscillator circuits. C319 was
	19A116080P7	Polyester: 0.1 µf ±20%, 50 VDCW.	J311			Q311*	19A115123P1 19A116755P1	Silicon, NPN. Silicon, NPN; sim to Type 2N3947.	R330	3R77P512J	Composition: 5100 ohms ±5%, 1/2 w.	11	İ	Earlier than REV J in G1:			Sprague Type 19C180.	
382	19A116080P109	Polyester: 0.22 µf ±10%, 50 VDCW.	J312	19B205689G2	Connector: 18 contacts.	Q311*	19811073321	In 197402429G1 of REV M and earlier:	R331	3R77P513J	Composition: 51,000 ohms ±5%, 1/2 w.			Earlier than REV H in G2, G3:			DIODES AND RECTIFIERS	REV. C - (25-33 MHz Receiver Board 19D402429-G1 Only) REV. B - (33-42 MHz Receiver Board 19D402429-G2 Only) REV. B - (42-50 MHz Receiver Board 19D402428-G3 only)
383	5495670P3	Electrolytic: 5 µf +75% -10%, 6 VDCW; sim to Sprague 30D125A1.		1	INDUCTORS			In 19D402429G2, G3 of REV L and earlier:	R332	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.		19B204808G1	Resistor Assembly. Includes resistor, variable, carbon film: 50,000 ohms ±20%, 0.1 w.	CR425	7777146P3	Germanium; sim to Type 1N90.	To reduce squelch clipping at high signal levels. C404 was adde
384*	5494481P114	Ceramic disc: 2000 pf ±10%, 500 VDCW; sim to	L301	19C303583G3	Coil. Includes tuning slug 19B200497P2.		19Al15123Pl	Silicon, NPN.	R333	3R77P333K	Composition: 33,000 ohms $\pm 10\%$, $1/2$ w.	R370	3R77P513J	Composition: 51,000 ohms ±5%, 1/2 w.				the top of CR308 to the top of R364.
3047	34544617114	RMC Type JF. Deleted by REV A.	L302	19C303583G4	Coil. Includes tuning slug 19B200497P2.	Q312	19A115300P4	Silicon, NPN. Silicon, NPN: sim to Type 2N5210.	R334	3R77P202J	Composition: 2000 ohms ±5%, 1/2 w.	R371	3R77P102J	Composition: 1000 ohms ±5%, 1/2 w.	J425	4033513P4	Contact, electrical: sim to Bead Chain L93-3.	REV. D - (25-33 MHz Receiver Board 19D402429-G1 Only) REV. C - (33-42 MHz Receiver Board 19D402429-G2 Only) REV. C - (42-50 MHz Receiver Board 19D402429-G3 Only)
385	5496267P2	Tantalum: 47 μf ±20%, 6 VDCW; sim to Sprague Type 150D.	L303	19C303583G2	Coil. Includes tuning slug 19B200497P2.	Q313*	19A116774P1	Silicon, NPN; sim to Type 2N5210. In 19D402429Gl of REV L and earlier:	R336	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	R372	3R77P202J	Composition: 2000 ohms ±5%, 1/2 w.	J429			To improve squelch operation temperature extremes and to protect
386*	19A116080P5	Polyester: .047 µf ±20%, 50 VDCW.	L304	19C303583G1	Coil. Includes tuning slug 19B200497P2.			In 19D402429G2, G3 of REV K and earlier:	R337	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.	R373*	19B209358P106	Variable, carbon film: approx 300 to 10,000 ohms ±10%, 0.25 w; sim to CTS Type X-201.				istor Q301 from very strong signals. CR309 was added across the emitter and base of Q301. R360 was deleted. C368, C392 and R36
		Earlier than REV A:	L305 and	19B204932G2	Coil. Includes tuning slug 19B200497P2.		19A115123P1	Silicon, NPN.	R338	3R77P102J	Composition: 1000 ohms ±5%, 1/2 w.	11		Earlier than REV J in G1:	L425	19B204752G2	Coil. Includes tuning slug 7160519P1.	changed.
	5491189P105	Polyester: .068 μf ±20%, 50 VDCW,	L306	19B204932G1	Coil Assembly.	Q314*	19A116774P1	Silicon, NPN; sim to Type 2N5210.	R339	3R77P331K	Composition: 330 ohms ±10%, 1/2 w. Composition: 51.000 ohms ±5%, 1/2 w.	11		Earlier than REV H in G2, G3:	L426	19B204752G1	Coil. Includes tuning slug 7160519P1.	REV. E - (25-33 MHz Receiver Board 19D402429-G1 Only) REV. D - (33-42 MHz Receiver Board 19D402429-G2 Only) REV. D - (42-50 MHz Receiver Board 19D402429-G3 Only)
387	19Al16080P109	Polyester: 0.22 μf ±10%, 50 VDCW.	L307 L308*	19B204932G1 19A115711P1	Transformer, freq: 455 KHz; sim to Automatic			In 19D402429G1 REV N-S: In 19D402429G2, G3 REV M-R:	R340 and R341	3R77P513J	Composition: 51,000 onms 15%, 1/2 w.		19B204808G2	Resistor Assembly. Includes resistor, variable, carbon film: 10,000 ohms ±20%, 0.1 w.		1		
888	5494481P116	Ceramic disc: 3000 pf ±10%, 500 VDCW; sim to RMC Type JF Discap.	thru L315*	19411371191	Mfg EX12670.		19A116755P1	Silicon, NPN; sim to Type 2N3947.	11	3R152P681K	Composition: 680 ohms ±10%, 1/4 w.	R374	3R77P300J	Composition: 30 ohms ±5%, 1/2 w.	Q425	19A115245P1	Silicon, NPN.	To improve temperature stability at temperature extremes. Chang C334 and C338.
389	5494481P112	Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC	1310		Earlier than REV J in Gl: Earlier than REV H in G2, G3:			In 19D402429G1 of REV M and earlier: In 19D402429G2. G3 of REV L and earlier:	R342 R343	3R77P682K	Composition: 6800 ohms ±10%, 1/2 w.	R375	3R77P472J	Composition: 4700 ohms ±5%, 1/2 w.	and Q426			REV. F - (25-33 MHz Receiver Board 19D402429-G1 Only) REV. E - (33-42 MHz Receiver Board 19D402429-G2 Only) REV. E - (42-50 MHz Receiver Board 19D402429-G3 Only)
369	04041011111	Type JF.		19C303062G6	Coil. Includes tuning slug 19B200497P2.				R344	3R77P104K	Composition: 0.1 megohm ±10%, 1/2 w.	R376	19A116278P444	Metal film: 0.28 megohm ±2%, 1/2 w.		1	2222222	REV. E - (42-50 MHz Receiver Board 19D402429-G3 Only)
390	7491827P5	Ceramic disc: 0.1 µf +80% -30%, 50 VDCW; sim to Sprague Type 36C172.	L316*	19A115711P2	Transformer, freq: 455 KHz; sim to Automatic		19A115123P1 19A115300P2	Silicon, NPN. Silicon, NPN; sim to Type 2N3053.	R345*	3R77P103J	Composition: 10,000 ohms ±5%, 1/2 w.	and R377	1		2405	3R152P123J	RESISTORS	To minimize the affects of line voltage transients on receiver operation. Added R378.
391*	19A116080P105	Polyester: 0.047 µf ±10%, 50 VDCW.			Mfg EX12671.	Q315 Q316*	19A115300P2	Silicon, NPN; sim to Type 2N3947.			In 19D402429G1 REV M-T:	R378*	3R152P101K	Composition: 100 ohms ±10%, 1/4 w. Added in G1 by REV F. Added in G2 and G3 by REV E.	R425 and R426	3R152P123J	Composition: 12,000 onms 13%, 1/4 w.	
		In 19D402429Gl of REV L and earlier: In 19D402429G2, G3 of REV K and earlier:		1	Earlier than REV J in Gl: Earlier than REV H in G2, G3:	Q316*	19811073371	In 19D402429Gl of REV M and earlier:			In 19D402429G2, G3 REV L-S:	R379*	3R152P511J	Composition: 510 ohms ±5%, 1/4 w. Added in Gl	R420	3R152P202J	Composition: 2000 ohms ±5%, 1/4 w.	REV. G - (25-33 MHz Receiver Board 19D402429-G1 Only) REV. F - (33-42 MHz Receiver Board 19D402429-G2 Only) REV. F - (42-50 MHz Receiver Board 19D402429-G3 Only)
		In 19D402429G2, G3 of REV R and earlier. Polvester: 0.22 µf ±10%, 50 VDCW.		19C303062G6	Coil. Includes tuning slug 19B200497P2.			In 19D402429G2, G3 of REV L and earlier:		3R77P622J	Composition: 6200 ohms ±5%, 1/2 w.			by REV L. Added in G2, G3 by REV K.	R428	3R152P511J	Composition: 510 ohms ±5%, 1/4 w.	To eliminate 455 kHz from the squelch circuit and lower maximum
	19A116080P109	Polyester: .01 µf ±20%, 50 VDCW.	L317*	19A115711P6	Transformer, freq: 455 KHz; sim to TOKO PEFCN-14733-CX12.		19A115123Pl	Silicon, NPN.			In 19D402429Gl of REV L and earlier: In 19D402429G2, G3 of REV K and earlier:	R380*	3R152P512J	Composition: 5100 ohms ±5%, 1/4 w. Added in G1 by REV K. Added in G2, G3 by REV J.	and R429	SK10210110	Campos 110 10 10 10 10 10 10 10	opening level. Changed C377.
392*	19A116080P1	In Gl REV C or earlier:			Earlier than REV J in Gl:				11	3R77P153K	Composition: 15,000 ohms $\pm 10\%$, $1/2$ w.	R381*	3R152P472K	Composition: 4700 ohms ±10%, 1/4 w. Added to 19D402429G1 by REV M.	R430	3R152P202J	Composition: 2000 ohms ±5%, 1/4 w.	REV. H - (25-33 MHz Receiver Board 19D402429-G1 Only) REV. G - (33-42 MHz Receiver Board 19D402429-G2 Only) REV. G - (42-50 MHz Receiver Board 19D402429-G3 Only)
		In G2 and G3 REV B or earlier:			Earlier than REV H in G2, G3:	R301	3R77P272J	Composition: 2700 ohms ±5%, 1/2 w.	R346	3R77P332K	Composition: 3300 ohms ±10%, 1/2 w.	11		Added to 19D402429G2, G3 by REV L. Deleted in 19D402429G1 by REV S.	R431	3R152P123J	Composition: 12,000 ohms ±5%, 1/4 w.	To improve temperature compensation of high IF circuits. Change
	7491827P2	Ceramic disc: .01 μf +80% -30%, 50 VDCW; sim to Sprague 19C180.		19C303062G4	Coil. Includes tuning slug 19B200497P2.	R302	3R77P103K	Composition: 10,000 ohms $\pm 10\%$, $1/2$ w.	R347	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.	11	1	Deleted in 19D402429G2, G3 by REV R.	and R432			C329; and C331.
C393	19Al16080Pl09	Polyester: 0.22 µf ±10%, 50 VDCW.	L318*	19A115711P7	Transformer, freq: 455 KHz; sim to TOKO PEFCN-14734-ENL2.	R303	3R77P102K	Composition: 1000 ohms ±10%, 1/2 w.	R348	3R77P332K	Composition: 3300 ohms ±10%, 1/2 w.			THERMISTORS	R433	3R152P472J	Composition: 4700 ohms ±5%, 1/4 w.	To utilize improved bypass capacitors in low IF. Changed C357, C362, and C365.
C394	5495670P13	Electrolytic: 2 µf +75% -10%, 25 VDCW; sim to			Earlier than REV J in G1:	R304	3R77P471K	Composition: 470 ohms ±10%, 1/2 w.	R349	3R77P221K	Composition: 220 ohms ±10%, 1/2 w.	RT301	5490828P29	Rod: 22,800 ohms ±5% res at 25°C, 1 w max input at 40°C; sim to Carborundum Type 723B-1.			SOCKETS	•
		Sprague Type 30D. Polyester: 0.1 µf ±10%, 50 VDCW.	l i		Earlier than REV H in G2, G3: Coil. Includes tuning slug 19B200497P2.	R305	3R77P433J	Composition: 43,000 ohms ±5%, 1/2 w.	R350	3R77P332J	Composition: 3300 ohms ±5%, 1/2 w.	11			XY425	5490277P1	Transistor: 4 contacts, low-loss mica-filled	REV. J - (25-33 MHz Receiver Board 19D402429-G1 Only) REV. H - (33-42 MHz Receiver Board 19D402429-G2 Only) REV. H - (42-50 MHz Receiver Board 19D402429-G3 Only)
C395	19A116080P107	Polyester: .01 µf ±5%, 50 VDCW.		19C303062G5 5491736P2	Inductor: 240 mh ±10% ind at 0.5 v, 270 ohms	R306	3R77P224K	Composition: 0.22 megohm ±10%, 1/2 w.	R351	3R77P152J	Composition: 1500 ohms ±5%, 1/2 w. Composition: 7500 ohms ±5%, 1/2 w.	RT302	5490828P28	Rod: 8750 ohms $\pm 5\%$ res at 25° C, 1 w max input at 40° C; sim to Carborundum Type $723F-2$.	and XY426	04502	phenolic; sim to Elco 3303.	To facilitate manufacturing and procurement of parts. Changed
C396 C397	19A116080P201 5496203P117	Ceramic disc: 47 pf ±10%, 500 VDCW, temp coef	L319	5491736P2	max DC res; sim to Aladdin 33-161.	R307	3R77P102J	Composition: 1000 ohms ±5%, 1/2 w.	R352	3R77P752J 3R77P472K	Composition: 4700 ohms ±10%, 1/2 w.	11		CRYSTALS		Ì		L318, R367 and R373.
C397	5490203F117	-3300 PPM.	<u> </u>		PLUGS	R308	3R152P331K	Composition: 330 ohms ±10%, 1/4 w. Composition: 100 ohms ±10%, 1/2 w.	R353 and R354	3R11P412R	Composition. The chart 220%, 572 at	Y301	19B206356P1	Quartz: antiresonant, frequency 4805.00 KHz.		1		REV. K - (25-33 MHz Receiver Board 19D402429-G1 Only) REV. J - (33-42 MHz Receiver Board 19D402429-G2 Only) REV. J - (42-50 MHz Receiver Board 19D402429-G3 Only)
398	5496219P656	Ceramic disc: 51 pf ±5%, 500 VDCW, temp coef -470 PPM.	P301	4029840P2	Contact, electrical: sim to Amp 42827-2.	R309*	3R77P101K	In 19D402429Gl of REV L and earlier:	R355*	3R77P332K	Composition: 3300 ohms ±10%, 1/2 w.	1301	198200330F1	quartz. anticesonant, require,			NOTE: When reordering give GE Part Number and specify exact frequency needed.	To prevent squelch lock-up at high signal levels. Deleted C404.
C399	5496267P10	Tantalum: 22 µf ±20%, 15 VDCW; sim to Sprague	thru P303] [In 19D402429G2, G3 of REV K and earlier:	R355	0	In Models earlier than REV A:	11		OSCILLATOR BOARDS 1-Freq Board Model 4EG19A10 (19C303591G1) 2-Freq Board Model 4EG19A11 (19C303591G2)			25-33 MHz Crystal Frequency = (OF +5.26 MHz)	Changed CR308.
		Type 150D. Ceramic disc: 47 pf ±10%, 500 VDCW, temp coef	P304	7147199P1	Connector: 1 male contact; sim to Winchester	1	3R77P471K	Composition: 470 ohms $\pm 10\%$, $1/2$ w.		3R77P222K	Composition: 2200 ohms ±10%, 1/2 w.			2-Freq Board Model 4EG19All (19C303591G2)			33-42 MHz Crystal Frequency = (<u>OF -5.26 MHz</u>)	REV. L - (25-33 MHz Receiver Board 19D402429-G1 Only) REV. K - (33-42 MHz Receiver Board 19D402429-G2 Only) REV. K - (42-50 MHz Receiver Board 19D402429-G3 Only)
C400	5496219P817	-1500 PPM.	and P305		Electronics 21803.	R310	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	R356*	3R77P621J	Composition: 620 ohms ±5%, 1/2 w.	11	1	CAPACITORS				
C401	5496219P369	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -150 PPM.	1	1	TRANSISTORS	R311	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.			In Models earlier than REV A:	C425	5491271P106	Variable, subminiature: approx 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189.			42-50 MHz Crystal Frequency = (<u>OF -5.26 MHz</u>)	To improve discriminator idling and tuning. Added R379.
C402	5490008P11	Silver mica: 22 pf ±5%, 500 VDCW; sim to Electro	Q301*	19A116859Pl	Silicon, NPN; sim to Type 2N5032 or 2N3570.	R312	3R77P222K	Composition: 2200 ohms ±10%, 1/2 w.		3R77P431J	Composition: 430 ohms ±5%, 1/2 w.		5496218P653	Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef	Y425	19B206357P1	Quartz: antiresonant, freq range 12-19 MHz.	REV. M - (25-33 MHz Receiver Board 19D402424-Gl only)
C402	3490008711	Motive Type DM-15.		1	In 19D402429Gl of REV R and earlier: In 19D402429G2, G3 of REV P and earlier:	R313	3R77P331K	Composition: 330 ohms ±10%, 1/2 w. Composition: 10,000 ohms ±10%, 1/2 w.	R357	3R77P431J	Composition: 430 ohms ±5%, 1/2 w.	C426	54902182055	-470 PPM.	and Y426			REV. M - (25-33 MHz Receiver Board 19D402424-G1 only) REV. L - (33-42 MHz Receiver Board 19D402429-G2 only) REV. L - (42-50 MHz Receiver Board 19D402429-G3 only)
C403	5496267P10	Tantalum: 22 μf $\pm 20\%$, 15 VDCW; sim to Sprague Type 150D.		19A115342P1	Silicon, NPN.	R314	3R77P103K	Composition: 12,000 ohms ±10%, 1/2 w.	R358*	3R77P123J	Composition: 12,000 ohms ±5%, 1/2 w.	C427	5490008P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.			MISCELLANEOUS	To improve discriminator "idling", to increase maximum squelch of level, and to increase squelch clopping at 3000 Hz. Changed R309
C404*	7489162P139	Silver mica: 330 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15. Added in G1 by REV C,	Q302	19A115342P1	Silicon, NPN.	R315*	3R77P123K	In 19D402429Gl of REV R and earlier:			In 19D402429G1 REV N and P: In 19D402429G2, G3 REV M and N:	C428	7491827P2	Ceramic disc: .01 uf +80% -30%, 50 VDCW; sim to		4036555Pl	Insulator, washer: nylon. (Used with Q312 and	R345, C355, C356, C391, Q305, Q306, and Q313. Added R381.
		neleted in G1 by REV K Added in G2 and G3 by	Q303*	19A115910P1	Silicon, NPN; sim to Type 2N3904.	11		In 19D402429G2, G3 of REV P and earlier:	11	3R77P303J	Composition: 30,000 ohms ±5%, 1/2 w.			Sprague Type 190180.		4036555P1	Q315).	REV. N - (25-33 MHz Receiver Board 19D402429-Gl only)
		REV B, Deleted in G2, G3 by REV J.			In 19D402429Gl of REV P and earlier: In 19D402429G2, G3 of REV N and earlier:	11	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.		1	In 19D402429Gl of REV M and earlier:	C429 and	5496218P54	Ceramic disc: 43 pf ±5%, 500 VDCW, temp coef 0 PPM.				REV. N - (25-33 MHz Receiver Board 190402429-Gl only) REV. M - (33-42 MHz Receiver Board 190402429-G2 only) REV M - (42-50 MHz Receiver Board 190402429-G3 only)
		DIODES AND RECTIFIERS		10.1115.00071	Silicon, NPN.	R316	3R77P392K	Composition: 3900 ohms ±10%, 1/2 w.	11		In 19D402429G2, G3 of REV L and earlier: Composition: 6200 ohms ±5%, 1/2 w.	C430		Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to				To incorporate new transistors. Changed Q303, Q307, Q308, Q309,
CR301	7777146P3	Germanium; sim to Type 1N90.	0004	19A115889P1 19A115342P1	Silicon, NPN.	R317	3R77P331K	Composition: 330 ohms ±10%, 1/2 w.		3R77P622J	Composition: 330 ohms ±10%, 1/2 w.	C431	7491827P2	Sprague Type 19C180.			1	Q311, Q314, and Q316. Changed R358.
and CR302			Q304 Q305*	19A115342F1	Silicon, NPN; sim to Type 2N5210.	R318	3R77P101K	Composition: 100 ohms ±10%, 1/2 w. Composition: 10,000 ohms ±10%, 1/2 w.	R359	3R77P331K 3R152P104		C432	5491271P106	Variable, subminiature: approx 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189.				
CR303	19A115250Pl	Silicon.	and Q306*	13,113,111		R319	3R77P103K	Composition: 33,000 ohms ±10%, 1/2 w.	R360*	381529104	Composition: 0.1 megohm ±5%, 1/4 w. Deleted from G1 by REV D. Deleted from G2 and G3 by REV C.		5496218P653	Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef				
CR304	1		Q 300+		In 19D402429G1 of REV L and earlier: In 19D402429G2, G3 of REV K and earlier:	R320	3R77P333K	Composition: 2000 ohms ±5%, 1/2 w.	R361*	3R77P823J	Composition: 82,000 ohms ±5%, 1/2 w.	C433	5496218P653	-470 PPM.				
CR305 and	7777146P3	Germanium; sim to Type 1N90.		19A115889Pl	Silicon, NPN.	R321	3R77P202J	Composition: 5100 ohms ±5%, 1/2 w.	N301*	JK//F0250	In G1 REV C or earlier:	C434	5490008P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.				REV. P - (25-33 MHz Receiver Board 190402429-Gl only) REV. N - (33-42 MHz Receiver Board 190402429-G2 only) REV. N - (42-50 MHz Receiver Board 190402429-G3 only)
CR306			Q307	19A115889P1	Silicon, NPN.	R322 R323	3R77P512J	Composition: 10,000 ohms ±10%, 1/2 w.			In G2 and G3 REV B or earlier:	C435	7491827P2	Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to				
CR307	4036887P6	Silicon, Zener. Silicon, Zener. Deleted in G1 by REV K. Deleted	thru			K323	SR / /PIUSR			3R152P753	Composition: 75,000 ohms ±5%, 1/4 w.	and C436		Sprague Type 19C180.				To improve frequency response. Changed C381.
CR308*	4036887P3	Silicon, Zener. Deleted in GI by REV K. Deleted in G2, G3 by REV J.							R362	3R77P332J	Composition: 3300 ohms ±5%, 1/2 w.							REV. R - (25-33 MHz Receiver Board 19D402429G1) REV. P - (33-42 MHz Receiver Board 19D402429G1) REV. P - (42-50 MHz Receiver Board 19D402429G3)
									R363	3R77P222J	Composition: 2200 ohms ±5%, 1/2 w. Composition: 15,000 ohms ±5%, 1/2 w.			· ·				REV. P - (42-50 MHz Receiver Board 19D402429G3)
1									R364	3R77P153J	Composition: 13,000 onms 13%, 1/2 w.	-						
					-						-			-				

as added from

protect trans-oss the and R361 were

ximum squelch

Changed C325,

C35**7,** C360,

anged L308-

elch opening ed R309,

Q309, Q310,

To improve operation of audio BIAS control. Changed R358, Q303 and Q310.

REV. S - (25-33 MHz Receiver Board 19D402429G1)
REV. R - (33-42 MHz Receiver Board 19D402429G2)
REV. R - (42-50 MHz Receiver Board 19D402429G3)

To improve receiver sensitivity. Deleted R381. Changed R315 and C333.

REV. T - (25-33 MHz Receiver Board 19D402429G1)
REV. S - (33-42 MHz Receiver Board 19D402429G2)
REV. S - (42-50 MHz Receiver Board 19D402429G3)

To increase maximum squelch opening.
Changed R366 and Q314.

REV. U - (25-33 MHz Receiver Board 19D402429G1) REV. T - (33-42 MHz Receiver Board 19D402429G2) REV. T - (42-50 MHz Receiver Board 19D402429G3) To improve squelch operation. Changed R345.

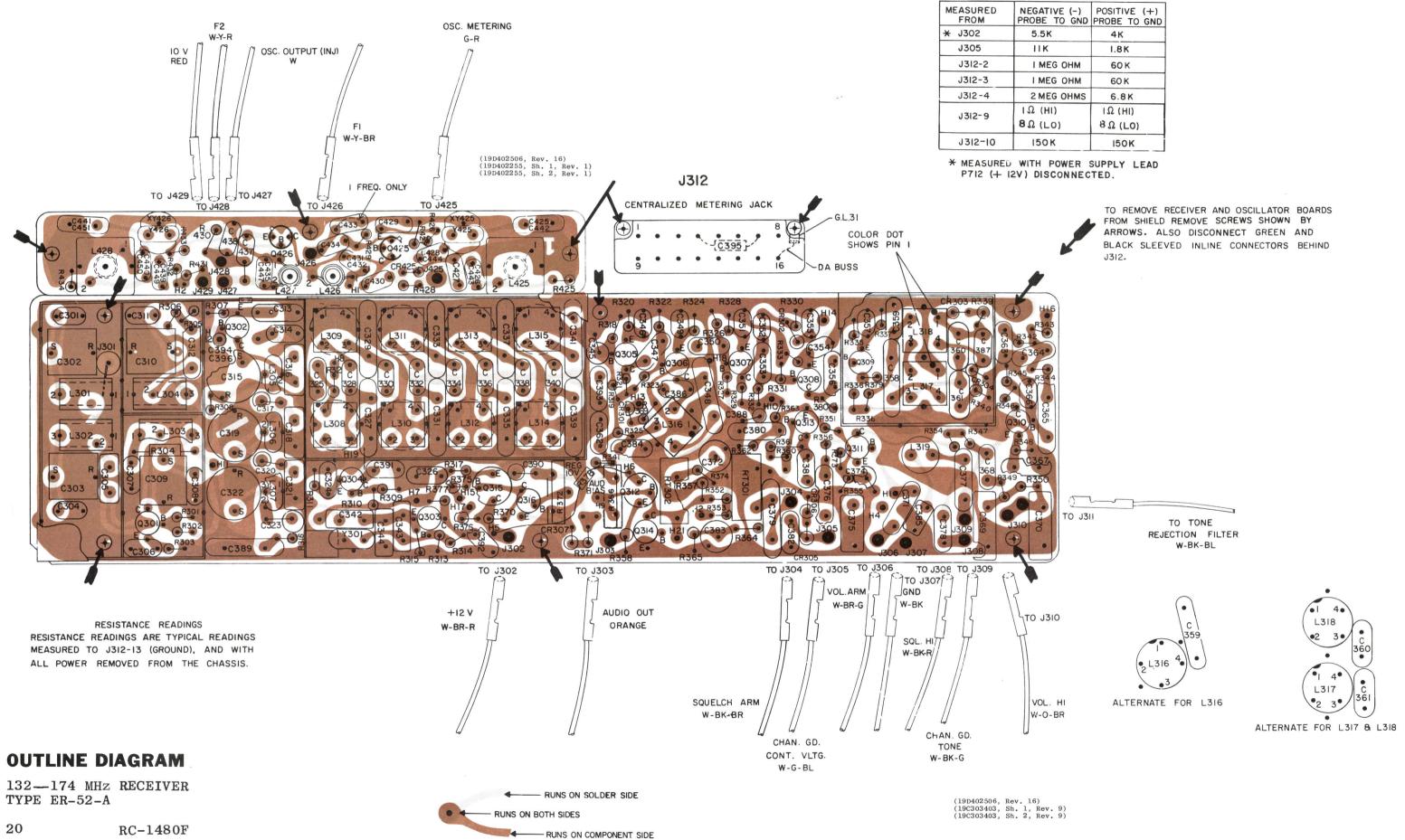
PARTS LIST

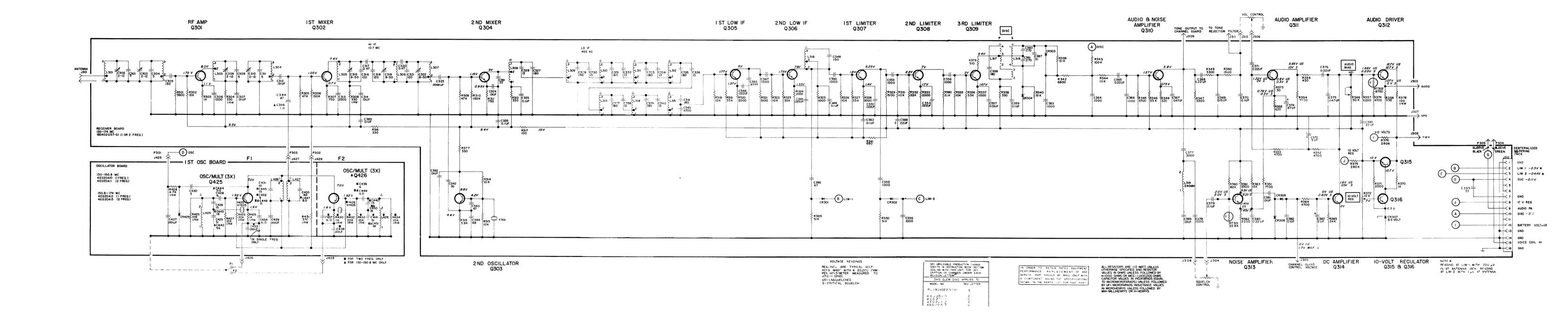
LBI-3759D

132-174 MHz RECEIVER - TYPE ER-52-A 132-174 MHz FIRST OSCILLATOR - MODELS 4EG20A10-13

C301 19Al16656P5J8 Ceramic dime: 5 pf 10.5 pf, 500 VDCW, temp coef -80 PPM. C302 and 5491271P106 Yariable, subminiature: 2.1-12.7 pf, 750 v peak; sin to EF Johnson 189. C303 19Al16656P5J8 Ceramic dime: 5 pf 10.5 pf, 500 VDCW, temp coef -80 PPM. C305 5490008P131 Silver mica: 150 pf 110%, 500 VDCW; sim to Electro Motive Type DM-15. C306* 19Al16655P20 Ceramic dime: 1000 pf 110%, 1000 VDCW; sim to Electro Motive Type DM-15. C307 7491827P102 Ceramic dime: .001 µf +100% -0%, 500 VDCW; sim to Sprague Type 12BCC4. C308 19Al16656P5J8 Ceramic dime: .001 µf +100% -0%, 500 VDCW; sim to Sprague Type 19Cl80. C309 19Al16656P5J8 Ceramic dime: .5 pf 10.5 pf, 500 VDCW, temp coef -80 PPM. C309 2491271P106 Yariable, subminiature: 2.1-12.7 pf, 750 v peak; sin to EF Johnson 189. C311 19Al16656P5J8 Ceramic dime: .5 pf 10.5 pf, 500 VDCW, temp coef -80 PPM. C312 7491393P2 Ceramic dime: .01 µf +100% -0%, 500 VDCW; sim to Sprague Type 12BC4. C313* 5494481P114 Ceramic dime: .000 pf, 1000 VDCW; sim to SMC Type JF Dimeap. Earlier than EEV E: C491393P1 Ceramic dime: .01 µf +100% -0%, 500 VDCW; sim to Sprague Type 12BC4. C314 7491393P1 Ceramic dime: .01 µf +100% -0%, 500 VDCW; sim to Sprague Type 12BC4. C315 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW; sim to Sprague Type 19Cl80. C316 5490008P29 Silver mica: 120 pf 15%, 500 VDCW; sim to Sprague Type 19Cl80. C317 7130348P1 Molded, phen: 0.47 pf 1.047 pf 500 VDCW; temp coef -750 PPM; sim to Verie S57-36. C320 7130348P1 Molded, phen: 0.47 pf 1.047 pf, 500 VDCW, temp coef 0 PPM; sim to Verie S57-36. C321 549046P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef 0 PPM; sim to Verie S57-36. C322 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef 0 PPM; sim to Verie S57-36. C323 7491930P4 Polyester: .006 pf 20%, 500 VDCW; sim to Electro Motive Type DM-15. C324* 19Al16690P1 Polyester: .006 pf 20%, 500 VDCW; sim to Selectro Motive Type DM-15. C324* 19Al16690P1 Polyester: .006 pf 20%, 500 VDCW; sim to Selectro Motive Type DM-15. C324* 19Al16690P1 Polyester: .006 pf 20%,	SYMBOL	GE PART NO.	DESCRIPTION
C301 19Al16656P5J8 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM. C302 and c303 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM. C303 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM. C304 Silver mica: 150 pf ±103, 500 VDCW, temp coef -80 PPM. C305 S490008P131 Silver mica: 150 pf ±103, 500 VDCW; sim to Electro Motive Type DM-15. C306* 19Al16655P20 Ceramic disc: 1000 pf ±103, 500 VDCW; sim to Electro Motive Type DM-15. C306* 19Al1665P20 Ceramic disc: 0.01 µf ±1003 -03, 500 VDCW; sim to Sprague Type 1921SC4. C307 7491827P102 Ceramic disc: 0.01 µf ±803 -303, 50 VDCW; sim to Sprague Type 1921SC4. C308 19Al16656P5J8 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW; sim to Sprague Type 1921SC4. C310 Variable, subminiature: 2.1-12.7 pf, 750 v peak sim to Ef Johnson 189. C311 19Al16656P5J8 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW; temp coef -80 PPM. C312 7491393P2 Ceramic disc: 0.1 µf ±1003 -03, 500 VDCW; sim to Sprague Type 1921SC4. C313* 5494481P114 Ceramic disc: 0.01 µf ±1003 -03, 500 VDCW; sim to RMC Type JF Discap. Earlier than REV H: C491393P1 Ceramic disc: 0.01 µf ±1003 -03, 500 VDCW; sim to RMC Type JF Discap. Earlier than REV E: C491393P1 Ceramic disc: 0.01 µf ±1003 -03, 500 VDCW; sim to Sprague Type 1921SC4. C314 7491827P2 Ceramic disc: 0.01 µf ±003 -03, 500 VDCW; sim to Sprague Type 1921SC4. C315 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to deffers Type JM-5/32. C316 5490008P29 Silver mica: 120 pf ±53, 500 VDCW; sim to Electro Motive Type DM-15. C317 7130348P1 Molded, phen: 0.47 pf ±047 pf 500 VDCW, temp coef 0 PPM; sim to deffers Type JM-5/32. C320 7130348P1 Molded, phen: 0.47 pf ±047 pf, 500 VDCW, temp coef 0 PPM; sim to deffers Type JM-5/32. C321 549046P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -700 PPM; sim to Geffers Type JM-5/32. C322 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -700 PPM; sim to Eleffers Type JM-5/32. C323			
C301 19A116656P5J8 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM. C302 and coef -80 PPM. Variable, subminiature: 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189. C303 19A116656P5J8 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM. C305 5490008P131 Silver mica: 150 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15. C306* 19A116655P20 Ceramic disc: 0.001 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap. Earlier than REV E:			19D402257G1
S491271P106 Variable, Subminiature: 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189.	C301	19A116656P5J8	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp
C304 19A116656P5J8 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM. C305 5490008P131 Silver mica: 150 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15. C306* 19A116655P20 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to Electro Motive Type DM-15. C307 7491827P102 Ceramic disc: .001 µf ±100% -0%, 500 VDCW; sim to Sprague Type 1219C4. C308 19A116656P5J8 Ceramic disc: .01 µf ±80% -30%, 50 VDCW; sim to Sprague Type 19C180. C309 304	and	5491271P106	Variable, subminiature: 2,1-12.7 pf, 750 v peak;
Silver mica: 150 pf ±10%, 500 VDCW; sim to Electro Motive Type Dm-15.		19A116656P5J8	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp
C306* 19A116655P20 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C305	5490008P131	Silver mica: 150 pf ±10%, 500 VDCW; sim to
7491393P1 Ceramic disc: .001 μf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4.	C306*	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to
to Sprague Type 1219C4. Ceramic disc: .01 μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. C308 19A116656P5J8 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM. C309 3nd 5491271P106 sim to EF Johnson 189. C311 19A116656P5J8 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM. C312 7491393P2 Ceramic disc: .01 μf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4. C313* 5494481P114 Ceramic disc: .2000 pf, 1000 VDCW; sim to RMC Type JF Discap. Earlier than REV R: Ceramic disc: .001 μf +100% -0%, 500 VDCW; sim to RMC Type JF Discap. Earlier than REV E: 7491393P1 Ceramic disc: .01 μf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4. C314 7491827P2 Ceramic disc: .01 μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. C315 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C316 549008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C317 7130348P1 Molded, phen: 0.47 pf ±.047 pf 500 VDCW, temp coef 0 PPM; sim to Erie 557-36. C319 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C320 7130348P1 Molded, phen: 0.47 pf ±.047 pf, 500 VDCW, temp coef -750 PPM; sim to Erie 557-36. C321 549046P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C322 549046P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C323 7491930P4 Molded, phen: 0.46 pf ±.047 pf, 500 VDCW, temp coef -750 PPM; sim to Erie 557-36. C324 19A116080P1 Polyester: .0068 μf ±20%, 100 VDCW; sim to Electro Motive Type DM-15. C324* 19A116080P1 Polyester: .0068 μf ±20%, 100 VDCW; sim to CE Type 61F. C324* 19A116080P1 Polyester: .01 μf ±20%, 50 VDCW.			Earlier than REV E:
Sprague Type 19C180.		7491393P1	Ceramic disc: .001 µf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4.
C309	C307	7491827P102	
sim to Ef Johnson 189. C311	C308	19A116656P5J8	
Coef -80 PPM. Coef -80 PPM. Coef -80 PPM. Ceramic disc: .01 µf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4. Camber disc: .2000 pf, 1000 VDCW; sim to RMC Type JF Discap. Earlier than REV H: 5494481P112 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap. Earlier than REV E: Ceramic disc: .001 µf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4. Can disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague Type 1219C4. Can disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Can disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Can disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Can disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Can disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague Type DM-15. Can disc: .01 µf ±047 pf 500 VDCW, temp coef or PPM; sim to Jeffers Type JM-5/32. Can disc: .01 µf ±047 pf, 500 VDCW; temp coef or PPM; sim to Erie 557-36. Can disc: .01 µf ±047 pf, 500 VDCW, temp coef or PPM; sim to Jeffers Type JM-5/32. Can disc: .01 µf ±047 pf, 500 VDCW, temp coef or PPM; sim to Erie 557-36. Can disc: .01 µf ±047 pf, 500 VDCW, temp coef or PPM; sim to Erie 557-36. Can disc: .01 µf ±20%, 50 VDCW; sim to GE Type GTP. Can disc: .01 µf ±20%, 50 VDCW; sim to GE Type GTP. Can disc: .01 µf ±80% -30%, 50 VDCW; sim to GE Type GTP. Can disc: .01 µf ±80% -30%, 50 VDCW; sim to GE Type GTP.	and	5491271P106	Variable, subminiature: 2.1-12.7 pf, 750 v peak sim to EF Johnson 189.
C312 7491393P2 Ceramic disc: .01 µf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4. C313* 5494481P114 Ceramic disc: 2000 pf, 1000 VDCW; sim to RMC Type JF Discap. Earlier than REV H: 5494481P112 Ceramic disc: .1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap. Earlier than REV E: 7491393P1 Ceramic disc: .001 µf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4. C314 7491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. C315 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C316 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C317 7130348P1 Molded, phen: 0.47 pf ±.047 pf 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C318 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C319 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C320 7130348P1 Molded, phen: 0.47 pf ±.047 pf, 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C321 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW, temp coef -750 PPM; sim to Jeffers Type JM-5/32. C321 549008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C322 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C323 7491930P4 Polyester: .0068 µf ±20%, 100 VDCW; sim to GE Type 61F. C324* 19A116080P1 Polyester: .01 µf ±20%, 50 VDCW. Earlier than REV F: C491827P2 Ceramic disc: .01 µf ±80% -30%, 50 VDCW; sim to	C311	19A116656P5J8	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM.
C313*	C312	7491393P2	Ceramic disc: 01 uf +100% -0% 500 VDCW: sim
Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap. Earlier than REV E: 7491393Pl Ceramic disc: .C01 µf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4. C314 7491827P2 Ceramic disc: .O1 µf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. C315 5490446Pl Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C316 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C317 7130348Pl Molded, phen: 0.47 pf ±.047 pf 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C318 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C319 5490446Pl Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C320 7130348Pl Molded, phen: 0.47 pf ±.047 pf, 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C321 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C322 5490446Pl Variable, ceramic: 8-50 pf, 350 VDCW; sim to Electro Motive Type DM-15. C323 7491930P4 Polyester: .0068 µf ±20%, 500 VDCW; sim to GE Type 61F. C324* 19A116080Pl Polyester: .01 µf ±20%, 50 VDCW; sim to GE Type 61F. C324* Ceramic disc: .01 µf ±80% -30%, 50 VDCW; sim to Earlier than REV F:	C313*	5494481P114	Ceramic disc: 2000 pf, 1000 VDCW; sim to
RMC Type JF Discap. Earlier than REV E: 7491393P1 Ceramic disc: .C01 µf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4. C314 7491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. C315 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C316 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C317 7130348P1 Molded, phen: 0.47 pf ±.047 pf 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C318 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C319 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C320 7130348P! Molded, phen: 0.47 pf ±.047 pf, 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C321 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C322 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C321 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW; sim to Electro Motive Type DM-15. C322 7491930P4 Polyester: .0068 µf ±20%, 500 VDCW; sim to GE Type 61F. C324* 19416080P1 Polyester: .01 µf ±20%, 50 VDCW. Earlier than REV F: C491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to			
Ceramic disc: .COl μf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Gerupic Germic Sprague Type 19C180. Caramic disc: .Ol μf +80% -30%, 50 VDCW; sim to Germic disc: .Ol μf +80% -30%, 50 VDCW; sim to Germic disc: .Ol μf +80% -30%, 50 VDCW; sim to Germic disc: .Ol μf +80% -30%, 50 VDCW; sim to Caramic disc: .Ol		5494481P112	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
to Sprague Type 1219C4. C314 7491827P2 Ceramic disc: .01 \(\mu f \) +80% -30%, 50 VDCW; sim to Sprague Type 19C180. C315 5490446P1 Variable, ceramic: 8-50 \(pf \), 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C316 5490008P29 Silver mica: 120 \(pf \) ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C317 7130348P1 Molded, phen: 0.47 \(pf \) ±.047 \(pf \) 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C318 5490008P29 Silver mica: 120 \(pf \) ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C319 5490446P1 Variable, ceramic: 8-50 \(pf \), 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C320 7130348P1 Molded, phen: 0.47 \(pf \) ±.047 \(pf \), 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C321 5490008P29 Silver mica: 120 \(pf \) ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C322 5490446P1 Variable, ceramic: 8-50 \(pf \), 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C323 7491930P4 Polyester: .0068 \(\mu f \) ±20%, 100 VDCW; sim to GE Type 61F. C324* 19A116080P1 Polyester: .01 \(\mu f \) ±20%, 50 VDCW. Earlier than REV F: C491827P2 Ceramic disc: .01 \(\mu f \) +80% -30%, 50 VDCW; sim to		740120201	
Sprague Type 19C180.			to Sprague Type 1219C4.
C316 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C317 7130348P1 Molded, phen: 0.47 pf ±.047 pf 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C318 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C319 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C320 7130348P1 Molded, phen: 0.47 pf ±.047 pf, 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C321 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C322 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C323 7491930P4 Polyester: .0068 µf ±20%, 100 VDCW; sim to GE Type 61F. C324* 19A116080P1 Polyester: .01 µf ±20%, 50 VDCW. Earlier than REV F: C491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	C314	7491827P2	
Molded, phen: 0.47 pf ±.047 pf 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C318	C315	5490446P1	Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36.
Coef 0 PPM; sim to Jeffers Type JM-5/32. C318 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C319 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C320 7130348P1 Molded, phen: 0.47 pf ±.047 pf, 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C321 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C322 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C323 7491930P4 Polyester: .0068 µf ±20%, 100 VDCW; sim to GE Type 61F. C324* 19A116080P1 Polyester: .01 µf ±20%, 50 VDCW. Earlier than REV F: C491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	C316	5490008P29	Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C318 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C319 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C320 7130348P! Molded, phen: 0.47 pf ±.047 pf, 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C321 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C322 5490446Pl Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C323 7491930P4 Polyester: .0068 µf ±20%, 100 VDCW; sim to GE Type 61F. C324* 19A116080P1 Polyester: .01 µf ±20%, 50 VDCW. Earlier than REV F: C491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	C317	7130348P1	Molded, phen: 0.47 pf ±.047 pf 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32.
C319 5490446Pl Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C320 7130348Pl Molded, phen: 0.47 pf ±.047 pf, 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C321 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C322 5490446Pl Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C323 7491930P4 Polyester: .0068 µf ±20%, 100 VDCW; sim to GE Type 61F. C324* 19A116080Pl Polyester: .01 µf ±20%, 50 VDCW. Earlier than REV F: C491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	C318	5490008P29	Silver mica: 120 pf ±5%, 500 VDCW; sim to
C320 7130348Pl Molded, phen: 0.47 pf ±.047 pf, 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. C321 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C322 5490446Pl Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C323 7491930P4 Polyester: .0068 µf ±20%, 100 VDCW; sim to GE Type 61F. C324* 19A116080Pl Polyester: .01 µf ±20%, 50 VDCW. Earlier than REV F: C491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	C319	5490446P1	
C321 5490008P29 Silver mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C322 5490446Pl Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C323 7491930P4 Polyester: .0068 µf ±20%, 100 VDCW; sim to GE Type 61F. C324* 19Al16080Pl Polyester: .01 µf ±20%, 50 VDCW. Earlier than REV F: C491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	C320	7130348Pl	1
C322 5490446P1 Variable, ceramic: 8-50 pf, 350 VDCW, temp coef -750 PPM; sim to Erie 557-36. C323 7491930P4 Polyester: .0068 µf ±20%, 100 VDCW; sim to GE Type 61F. C324* 19A116080P1 Polyester: .01 µf ±20%, 50 VDCW. Earlier than REV F: Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	C321	5490008P29	Silver mica: 120 pf ±5%, 500 VDCW; sim to
C323 7491930P4 Polyester: .0068 µf ±20%, 100 VDCW; sim to GE Type 61F. C324* 19A116080P1 Polyester: .01 µf ±20%, 50 VDCW. Earlier than REV F: 7491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	C322	5490446P1	
C324* 19A116080P1 Polyester: .01 \(\mu f \pm 20\%, 50 \text{ VDCW}. \) Earlier than REV F: 7491827P2 Ceramic disc: .01 \(\mu f \pm 80\% - 30\%, 50 \text{ VDCW}; \) sim to	C323	7491930P4	Polyester: .0068 µf ±20%, 100 VDCW; sim
7491827P2 Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	C324*	19A116080P1	Polyester: .01 μf ±20%, 50 VDCW.
		7491827P2	Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to
		I	1

	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
	C325 and	19All6080Pl07	Polyester: 0.1 µf ±10%, 50 VDCW.	C348	5496219P367	Ceramic disc: 150 pf ±5%, 500 VDCW, temp coef
	C326 C327	5 4 96219P369	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef	C349*	19A116080P3	-150 PPM. Polyester: 0.022 µf ±20%, 50 VDCW.
_	C328*	5496219P43	-150 PPM. Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef		5492638P101	Earlier than REV K: Ceramic disc: 0.1 µf +100% -0%, 3 VDCW; sim to
			O PPM. In REV N and earlier:	C350	5494481P112	Sprague 54C23. Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to
11		5496219P42	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef O PPM.	C351*	19A116080P3	RMC Type JF. Polyester: 0.022 µf ±20%, 50 VDCW.
	C329	5496219P369	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -150 PPM.			Earlier than REV K:
	C330*	5496219P43	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef 0 PPM.		5492638P101	Ceramic disc: 0.1 µf +100% -0%, 3 VDCW; sim to Sprague 54C23.
		5.400010D40	In REV N and earlier:	C352	7491393P1	Ceramic disc: .001 µf +100% -0%, 500 VDCW; sim to Sprague 1219C4.
		5496219P42	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef O PPM.	C353	5494481P112	Ceramic disc: 1000 pf $\pm 10\%$, 1000 VDCW; sim to RMC Type JF.
	C331	5496219P369	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -150 PPM.	C354*	19A116080P3	Polyester: 0.022 µf ±20%, 50 VDCW. Earlier than REV K:
	C332*	5496219P43	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef 0 PPM.		5492638P101	Ceramic disc: 0.1 µf +100% -0%, 3 VDCW; sim to Sprague 54C23.
		5496219P42	In REV N and earlier: Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef	C355	7491393P1	Ceramic disc: .001 µf +100% -0%, 500 VDCW; sim to Sprague 121964.
	C333	5496219P369	O PPM. Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef	C356	5494481P112	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to
	C334*	5496219P43	-150 PPM. Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef	C357*	19A116080P1	Polyester: .01 µf ±20%, 50 VDCW.
			O PPM. In REV N and earlier:		7491827P2	Earlier than REV E: Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to
		5496219P42	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef 0 PPM.	C358	5496219P369	Sprague 19C180. Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef
	C335	5496219P369	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -150 PPM.	C359	19A116080P107	-150 PPM. Polyester: 0.1 µf ±10%, 50 VDCW.
	C336*	5496219P43	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef 0 PPM.	C360 and	5490008P37	Silver mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
			In REV N and earlier:	C361 C362	19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.
		5496219P42	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef 0 PPM.	C363	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF.
	C337	5496219P369	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -150 PPM.	C364 C365	19A116080P109	
	C338*	5496219P43	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef 0 PPM.	C366*	5494481P11	Polyester: 0.22 µf ±10%, 50 VDCW. Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF.
		5496219P42	In REV N and earlier: Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef			Earlier than REV J:
	C339	5496219P369	O PPM. Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef		5494481P107	Ceramic disc: 470 pf $\pm 20\%$, 1000 VDCW; sim to RMC Type JF.
	C340*	5496219P43	-150 PPM. Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef	C367 C368*	19A116080P5 19A116080P109	Polyester: 0.047 µf ±20%, 50 VDCW.
			In REV N and earlier:	0000	194110000109	Polyester: 0.22 µf ±10%, 50 VDCW. Earlier than REV C:
		5496219P42	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef 0 PPM.		5492638P107	Ceramic disc: 0.1 μf +80% -20%, 12 VDCW; sim to Sprague 20C202.
	C341	5496219P369	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -150 PPM.	C369*	19A116080P8	Polyester: 0.15 µf ±20%, 50 VDCW.
	C342	5496219P50	Ceramic disc: 30 pf ±5%, 500 VDCW, temp coef 0 PPM.		19B209243P7	Earlier than REV C: Polyester: 0.1 µf ±20%, 50 VDCW.
	C343	5490008P19	Silver mica: 47 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C370 C371	19A116080P7 19A116080P109	Polyester: 0.1 µf ±20%, 50 VDCW.
	C344	5490008P23	Silver mica: 68 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C372	5495670P3	Polyester: 0.22 µf ±10%, 50 VDCW. Electrolytic: 5 µf ±75% -10%, 6 VDCW;
	C345	7491930P3	Polyester: .0047 µf ±20%, 100 VDCW; sim to GE Type 61F.	C373*	5494481P114	sim to Sprague Type 30D. Ceramic disc: 2000 pf ±10%, 1000 VDCW; sim to
	C346*	19A116080P3	Polyester: 0.022 µf ±20%, 50 VDCW.	C374	5496267P2	RMC Type JF. Deleted by REV C. Tantalum: 47 µf ±20%, 6 VDCW; sim to Sprague
		5492638P101	Earlier than REV K:	C375*	19A116080P5	Type 150D. Polyester: 0.047 μf ±20%, 50 VDCW.
	C347	5492438P101	Ceramic disc: 0.1 µf +100% -0%, 3 VDCW; sim to Sprague 54C23.			Earlier than REV C:
	0011	0101101P112	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF.		19B209243P6	Polyester: .068 µf ±20%, 50 VDCW.
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SCHEMATIC DIAGRAM

132-174 MHz RECEIVER TYPE ER-52-A 21

$\frac{57}{s}$	YMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	
-				1.303*	19B204402G3	Coil Assembly.			200 CT CT CT CT CT CT CT CT CT CT CT CT CT	R352	3R77P472K	Composition: 4700 ohms ±107, 1/2 w.	C426	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef	C449*	5496219P37	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp coe	i
1	376	19A116080P109	Polyester: 0.22 μf ±10%, 50 VDCW.	1,303*	19820440203	In Models earlier than REV E:	R301	3R77P392K		and R353			0.20		-80 PPM.			O PPM.	'
	377	5494481P116	Ceramic disc: 3000 pf $\pm 10\%$, 1000 VDCW; sim to RMC Type JF.		19B204402G2	Coil Assembly.	R302	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.	R354*	3R77P332K	Composition: 3300 ohms ±10%, 1/4 w.	C427	7491393P1	Ceramic disc: .001 µf +100% -0%, 500 VDCW; sim to Sprague 1219C4.			In Models of REV B and earlier:	, R
	378	5494481P112	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF.	L304	19B204402G3	Coil Assembly.	R303	3R77P102K	Composition: 1000 ohms ±10%, 1/2 w.			In Models earlier than REV C:	C428	5496219 P3 7	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp		5496219P39	Ceramic disc: 8 pf ±0.25 pf, 500 VDCW, temp coe 0 PPM.	1 "
	379	7491827P5	Ceramic disc: 0.1 µf +80% -30%, 50 VDCW; sim to	L305 and	19B204403G1	Coil Assembly.	R304	3R152P331K	Composition: 330 ohms $\pm 10\%$, $1/2$ w.		3R152P222K	Composition: 2200 ohms $\pm 10\%$, $1/4$ w.	C429*	5494481P112	Ceramic disc: 1000 pf ±107, 1000 VDCW; sim to	C450	5496219P245	Ceramic disc: 18 pf ±5%, 500 VDCW, temp coef -80 PPM.	
			Sprague 36C172.	L306			R305	3R77P473K	Composition: 47,000 ohms $\pm 10\%$, $1/2$ w.	R355*	3R77P621J	Composition: 620 ohms ±5%, 1/2 w.			RMC Type JF Discap.	C451	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef	R
1	380	19A116080P109	Polyester: 0.22 μf ±10%, 50 VDCW.	L307	19B204403G2	Coil Assembly.	R306	3R77P154K	Composition: 0.15 megohm ±10%, 1/2 w.			In Models earlier than REV C:			In Models of REV B and earlier:			-80 PPM.	
'	381*	19A116080Pl	Polyester: 0.01 µf ±20%, 50 VDCW. Earlier than REV E:	L308* thru	19All57llPl	Transformer, freq: 455 KHz; sim to Automatic Mfg EX12670.	R307	3R77P751J	Composition: 750 ohms ±5%, 1/2 w.	R356	3R152P431J 3R77P431J	Composition: 430 ohms ±5%, 1/4 w.		7491393P1	Ceramic disc: .001 μf +100% -0%, 500 VDCW; sim to Sprague Type 1219C4.			DIODES AND RECTIFIERS	
		7491827P2	Ceramic disc: .01 µf +80% -30%, 50 VDCW; sim to	L315*		Earlier than REV L:	R308	3R152P331K	Composition: 330 ohms ±10%, 1/4 w.	R357	3R77P622J	Composition: 430 ohms ±57, 1/2 w. Composition: 6200 ohms ±57, 1/2 w.	C430	5496219P34	Ceramic disc: 3 pf ±0.25 pf, 500 VDCW, temp	CR425	4038056P1	Germanium.	
:		İ	Sprague 19C180.		19C303062G6	Coil Assembly. Includes tuning slug 4038368Pl.	R309 R310	3R77P473K 3R77P154K	Composition: 47,000 ohms ±10%, 1/2 w. Composition: 0.15 megohm ±10%, 1/2 w.	R358	3R77P331K	Composition: 330 ohms ±10%, 1/2 w.	C431	5496219P241	Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp				-
1	382	19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.	L316*	19A115711P2	Transformer, freq: 455 KHz; sim to Automatic Mfg EX12671.	R311	3R77P751J	Composition: 750 ohms ±5%, 1/2 w.	R359*	3R152P104J	Composition: 0.1 megohm ±5%, 1/4 w. Deleted			coef -80 PPM.	J425	4033513P4	Contact, electrical: sim to Bead Chain L93-3.	
'	383	5495670P13	Electrolytic: 2 µf +75% -10%, 25 VDCW: sim to Sprague 30D.			Earlier than REV L:	R312	3R77P331K	Composition: 330 ohms $\pm 10\%$, $1/2$ w.	R360*	3R77P823J	by REV E.	C432	5496219P240	Ceramic disc: 9 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.	thru J429			
(384	19A116080P107	Polyester: 0.1 μ f $\pm 10\%$, 50 VDCW.		19C303062G6	Coil Assembly. Includes tuning slug 4038368Pl.	R313	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	R300*	3R11P823J	Composition: 82,000 ohms ±5%, 1/2 w. In Models earlier than REV E:	C433*	5494481P112	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.				
i	385	19A116080P201	Polyester: 0.01 μf ±5%, 50 VDCW.	L317*	19A115711P6	Transformer, freq: 455 KHz; sim to TOKO PEFCN-14733-CX12.	R314				3R152P753J	Composition: 75,000 ohms ±5%, 1/4 w.			In Models of REV B and earlier:	L425	19A121085G1	Coil Assembly. Includes tuning slug 19B200497P2	
'	2386	5496203P117	Ceramic disc: 47 pf ±10%, 500 VDCW, temp coef -3300 PPM.			Earlier than REV L:	R315	3R77P392K	Composition: 3900 ohms ±10%, 1/2 w.	R361	3R77P332J	Composition: 3300 ohms ±5%, 1/2 w.		7491393P1	Ceramic disc: .001 µf +100% -0%, 500 VDCW; sim	L426	19A121084G1	Coil Assembly. Includes tuning slug 19B200497P2	-
(387	5496219P656	Ceramic disc: 51 pf ±5%, 500 VDCW, temp coef		19C303062G4	Coil Assembly. Includes tuning slug 4038368Pl.	R316	3R77P331K	Composition: 330 ohms ±10%, 1/2 w.	R362	3R77P222J	Composition: 2200 ohms ±5%, 1/2 w.			to Sprague 1219C4.	L427	19A121083G1	Coil Assembly. Includes tuning slug 19B200497P2	\cdot
1.	388	5496267P10	-470 PPM. Tantalum: 22 μf ±20%, 15 VDCW; sim to	L318*	19A115711P7	Transformer, freq: 455 KHz; sim to TOKO PEFCN-	R317	3R77P101K	Composition: 100 ohms ±10%, 1/2 w.	R363	3R77P153J	Composition: 15,000 ohms ±5%, 1/2 w.	C434*	5496219P37	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	L428	19A121085G1	Coil Assembly. Includes tuning slug 19B200497P2	1
	.500	5450207F10	Sprague Type 150D.			14734-BNL2.	R318	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	R364	3R77P472K	Composition: 4700 ohms $\pm 10\%$, $1/2$ w.	İ		In Models of REV B and earlier:			TRANSISTORS	
	389	19A116080P7	Polyester: 0.1 μf ±20%, 50 VDCW.		19C303062G5	Earlier than REV L: Coil Assembly, Includes tuning slug 4038368Pl.	R319 R320	3R77P333K 3R77P202J	Composition: 33,000 ohms ±10%, 1/2 w.	R365	3R77P243J	Composition: 2400 ohms ±5%, 1/2 w.	İ	5496219P34	Ceramic disc: 3 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	Q425* and	19A115925P1	Silicon, NPN.	
	2390	5496267P10	Tantalum: 22 μf $\pm 20\%$, 15 VDCW; sim to Sprague Type 150D.	L319	5491736P2	Inductor: 240 mh ±10% ind at 0.5 v. 270 ohms	R321	3R77P512J	Composition: 2000 ohms ±5%, 1/2 w. Composition: 5100 ohms ±5%, 1/2 w.	R366*	19B209358P108	Variable, carbon film: approx 100 to 50,000 ohms ±10%, 0.25 w; sim to CTS Type X-201.	C435*	5496219P235	Ceramic disc: 4 pf ±0.25 pf, 500 VDCW, temp coef	Q426*		In Models earlier than REV B:	
	391	5490008P11	Silver mica: 22 pf ±5%, 500 VDCW; sim to			max DC res; sim to Aladdin 33-161.	R322	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.			Earlier than REV L:	1		-80 PPM.		19All5342Pl	Silicon, NPN.	
	392*	19A116080P1	Electro Motive Type DM-15. Polyester: .01 µf ±20%, 50 VDCW.				R323	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.		19B204808G1	Resistor Assembly. Includes resistor, variable, carbon film: 50,000 ohms ±20%, 0,1 w,		5496219P236	In Models earlier than REV A:				
			Earlier than REV F:	P301 thru	4029840P2	Contact, electrical: sim to Amp 42827-2.	R324	3R77P202J	Composition: 2000 ohms ±5%, 1/2 w.	R369	3R77P513J	Composition: 51,000 ohms ±5%, 1/2 w.		5490219P230	Ceramic disc: 5 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.	R425	3R152P103K		
	-	7491827P2	Ceramic disc: .01 μf +80% -30%, 50 VDCW: sim to	P303			R325	3R77P102K	Composition: 1000 ohms ±10%, 1/2 w.	R370	3R77P102J	Composition: 1000 ohms ±5%, 1/2 w.	C436*	7130348P1	Molded, phen: 0.47 pf ±.047 pf. 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. Deleted		3R152P203J	Composition: 20,000 ohms ±10%, 1/4 w.	
	C393	5496219P817	Sprague 19C180.	P304 and	7147199 P 1	Connector: 1 male contact; sim to Winchester Electronics 21803.	R326	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	R371	3R77P202J	Composition: 2000 ohms $\pm 5\%$, $1/2$ w.			by REV A.	R427	3R152P103K	Composition: 10,000 ohms ±107, 1/4 w.	
	2393	34902199017	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef -150 PPM.	P305			R327	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.	R372*	19B209358P106	Variable, carbon film: approx 75 to 10,000 ohms	C437*	5496219P37	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM,	R428	3R152P472K	Composition: 4700 ohms ±107, 1/4 w.	
	C394*	7130348Pl	Molded, phen: 0.47 pf \pm .047 pf, 500 VDCW, temp coef 0 PPM. Added by REV B.	0201	19A115342P1	TRANSISTORS	R328 R329	3R77P202J 3R77P512J	Composition: 2000 ohms ±5%, 1/2 w.			±10%, 0.25 w; sim to CTS Type X-201. Earlier than REV L:			In Models of REV B and earlier:	R429 and	3R152P102K	Composition: 1000 ohms ±10%, 1/4 w.	
	C395*	7489162P111	Mica: 22 pf ±10%, 500 VDCW; sim to Electro	Q301 and Q302	19A115342P1	Silicon, NPN.	R330	3R77P512J	Composition: 5100 ohms ±5%, 1/2 w. Composition: 51,000 ohms ±5%, 1/2 w.		19B204808G2	Resistor Assembly. Includes resistor, variable.		5496219P34	Ceramic disc: 3 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	R430			
	C396*	7130348P3	Motive Type DM-15. Added by REV B.	Q303	19A115889P1	Silicon, NPN; sim to Type 2N2712.	R331	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	2070		carbon film: .01 megohm ±20%, 0.1 w.	C438*	5494481P112	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to	R431	3R152P331K	Composition: 330 ohms ±10%, 1/4 w.	
	2350+	7130346F3	Molded, phen: 1 pf \pm .05%, 500 VDCW, temp coef 0 PPM. Added by REV B.	Q304	19A115342P1	Silicon, NPN.	R332	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.	R373 R374	3R77P300J 3R77P472J	Composition: 30 ohms ±5%, 1/2 w.			RMC Type JF Discap.	R432 R433	3R152P203J 3R152P103K	Composition: 20,000 ohms ±5%, 1/4 w.	
	C397*	7489162P139	Silver mica: 330 pf ±10%, 500 VDCW: sim to Electro Motive Type DM-15. Added by REV D.	Q305*	19A116774P1	Silicon, NPN: sim to Type 2N5210.	R333	3R77P202J	Composition: 2000 ohms ±5%, 1/2 w.	R375	19A116278P444	Composition: 4700 ohms ±5%, 1/2 w. Metal film: 0.28 megohm ±2%, 1/2 w.		7491393P1	In Models of REV B and earlier: Ceramic disc: .001 µf +100% -0%, 500 VDCW; sim	and R434	3R132P103R	Composition: 10,000 ohms ±10%, 1/4 w.	
			Deleted by REV M.	and Q306*		In REV R and earlier:	R335	3R77P103K	Composition: $10,000$ ohms $\pm 10\%$, $1/2$ w.	and R376		22, 1/2 w.	İ	7491393F1	to Sprague 1219C4.				
			DIODES AND RECTIFIERS		19A115889P1	Silicon, NPN; sim to Type 2N2712.	R336	3R77P333K	Composition: 33,000 ohms $\pm 10^{\circ}$, $1/2$ w.	R377	3R77P331K	Composition: 330 ohms ±10%, 1/2 w.	C439	5496219P37	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	XY425	5490277Pl	Transistor: 4 contact, low-loss mica-filled	
	CR301	4038056P1	Germanium.	Q307	19A115889P1	Silicon, NPN; sim to Type 2N2712.	R337	3R77P102J	Composition: 1000 ohms ±5%, 1/2 w.	R378	3R152P101K	Composition: 100 ohms ±10%, 1/4 w.	C440	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef	and XY426		phenolic; sim to Elco 3303.	
	CR302			thru Q309			R338 R339	3R77P331K 3R77P513J	Composition: 330 ohms ±10%, 1/2 w.	R379*	3R152P511J	Composition: 510 ohms ±5%, 1/4 w. Added by by REV N.	C441	5496219P56	-80 PPM. Ceramic disc: 51 pf ±5%, 500 VDCW, temp coef				
1	CR303 and	19A115250P1	Silicon.	Q310*	19A116774P1	Silicon, NPN; sim to Type 2N5210.	and R340	387793133	Composition: 51,000 ohms ±5%, 1/2 w.	R380*	3R152P512J	Composition: 5100 ohms ±5%, 1/4 w. Added by	(44)	3490219730	O PPM.			NOTE: When reordering give GE Part Number and specify exact freq needed.	
	CR304	400005673				In REV N and earlier:	R341	3R152P681K	Composition: $680 \text{ ohms } \pm 10\%$, $1/4 \text{ w}$.	1		REV M.	C442	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.			Crystal Freq = (OF -10.7 MHz) ÷ 3.	-
1	CR305 and CR306	4038056P1	Germanium.		19A115123P1	Silicon, NPN; sim to Type 2N2712.	R342	3R77P682K	Composition: 6800 ohms ±10%, 1/2 w.	R381*	3R152P472J	Composition: 4700 ohms $\pm 5\%$, $1/4$ w. Added by REV R. Deleted by REV S.	C443	5496219P245	Ceramic disc: 18 pf ±5%, 500 VDCW, temp coef	Y425	19B206221P1	Quartz: freq range 39 to 62 MHz.	
1	CR307	4036887P6	Silicon, Zener.	Q311*	19A116755P1	Silicon, NPN: sim to Type 2N3947.	R343	3R77P104K	Composition: 0.1 megohm ±10%, 1/2 w.			THERMISTORS	6444+	5406210027	-80 PPM.	and Y426			-
- 1	CR308*	4036887P3	Silicon, Zener. Deleted by REV M.		19A115123P1	In REV R and earlier: Silicon, NPN; sim to Type 2N2712.	R344*	3R77P103J	Composition: 10,000 ohms ±5%, 1/2 w.	RT301	5490828P29	Rod: 0.228 megohm ±5% res at 25°C, 1 w max input	C444*	5496219P37	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp coef -0 PPM.				
				Q312	19A115123P1 19A115300P4	Silicon, NPN; sim to Type 2N2/12. Silicon, NPN; sim to Type 2N3053.			In REV R and earlier:			at 40°C; sim to Globar 723B-1.			In Models of REV B and earlier:				
	J301	5496078P3	JACKS AND RECEPTACLES	Q313*	19A116774P1	Silicon, NPN: sim to Type 2N5210.		3R77P153K	Composition: 15,000 ohms $\pm 10^{\circ}$, $1/2$ w.	RT302	5490828P28	Rod: 8750 ohms $\pm 5\%$ res at 25 °C, 1 w max input at 40 °C; sim to Globar $723F-2$.		5496219P39	Ceramic disc: 8 pf ±0.25 pf, 500 VDCW, temp coef -0 PPM.				-
	J302	4033513P4	Receptacle, coaxial: sim to FXR 27-3. Contact, electrical: sim to Bead Chain L93-3.			In REV N and earlier:	R345	3R77P332K	Composition: 3300 ohms $\pm 10\%$, $1/2$ w.			CDVCTAL S	C445	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef				
	thru J311	1033313F4	contact, electrical: Sim to bead Chain 195-5.		19A115123P1	Silicon, NPN: sim to Type 2N2712.	R346 R347	3R77P333K 3R77P332K	Composition: 33,000 ohms ±10%, 1/2 w.	Y301	19A110215G1		and C446		-80 PPM.				
	J312	19B205689G2	Connector: 18 contacts.	Q314*	19A116774P1	Silicon, NPN; sim to Type 2N5210.	R348	3R77P221K	Composition: 3300 ohms ±10%, 1/2 w.	1002	10	quarter and resonant, freq 10210 laiz.	C447*	5496219P237	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp coef				-
	ĺ				1	In REV R and earlier:	R349	3R77P221R 3R77P332J	Composition: 220 ohms ±10%, 1/2 w. Composition: 3300 ohms ±5%, 1/2 w.			FIRST OSCILLATOR ASSEMBLY MODELS 4EG20A1013			In Models earlier than REV A:				
	L301	19B204402G4			19A115123P1	Silicon, NPN: sim to Type 2N2712.	R350	3R77P152J	Composition: 1500 ohms ±5%, 1/2 w.			19D402259G3 - Single Freq 132-150.8 MHz 19D402259G4 - Two Freq 132-150.8 MHz		5496219P238	Ceramic disc: 7 pf ±0.25 pf, 500 VDCW, temp coef				
1	L301 L302	19B204402G1	Coil Assembly.	Q315	19A115300P2	Silicon, NPN: sim to Type 2N3053.	R351	3R77P752J	Composition: 7500 ohms $\pm 5\%$, $1/2$ w.			19D402259G1 - Single Freq 150.8-174 MHz 19D402259G2 - Two Freq 150.8-174 MHz	C440÷	712024002	-80 PPM.	1			
			,	Q316*	19A116755P1	Silicon, NPN; sim to Type 2N3947.							C448*	7130348P3	Molded, phen: 1 pf ±.05 pf, 500 VDCW, temp coef 0 PPM; sim to Jeffers Type JM-5/32. Deleted by REV A.				
					19A115123P1	In REV R and earlier: Silicon, NPN; sim to Type 2N2712.				C425	5496219P56	Ceramic disc: 51 pf ±5%, 500 VDCW, temp coef		1					
						1,70						O PPM.		1					
					1														
	l																		
				J L			J L			L	1		L	1	L	L	L	<u> </u>	_l

PRODUCTION CHANGES

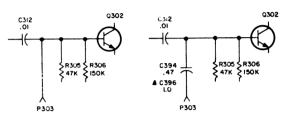
Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

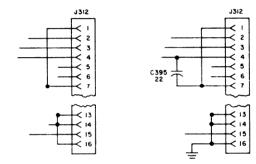
REV. A (19D402257-G1 only) - To match voice coil hi and ground of J312 to G-E Test Set 4EX3Al0. Moved VOICE COIL HI from J312-7 to J312-15. Moved GND from J312-15 to J312-7.

REV. B (19D402257-G1 only) - To improve systems spurious. Added C394, C395, C396, ground lug under mounting screw of J312, and jumper between ground lug and J312-16.

Elementary Diagram Canges

Changed to



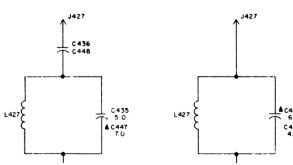


REV. C (19D402257-Gl only) - To improve audio response characteristics. Changed C368, C369, C375, R354 and R355. Deleted C373 from collector to base of Q311.

REV. A (4EG20A10-13 only) - To improve systems spurious. Deleted C436 and C448, and changed C435 and C447.

Elementary Diagram Changes

Changed to



REV. D (19D402257-Gl only) - To reduce squelch clipping at high signal levels. Added ${\tt C397}$.

REV. E (19D402257-G1 only) - To prevent squelch changes with temperature and to reduce gain of RF Amplifier. Changed C306, C313, C357, C381, L303 and R360. Deleted R359.

REV. F (19D402257-Gl only) - To improve temperature stability. Changed C324 and C392.

REV. G (19D402257-Gl only) - To minimize the affect of line voltage transients on receiver operation.

Added R378. REV. B (4EG20A10-13) - To imcorporate an improved transistor.

Changed Q425 and Q426.

 To prevent free-running of the oscilla-tor without a crystal. Changed C429, C433 and C438. REV. C (4EG20A10-13)

REV. H (19D402257-G1) - To improve 1st Mixer stability, Changed C313,

- To eliminate 450 kHz from the squelch circuit and lower maximum squelch opening level. REV. J (19D402257-G1

REV. K (19D402257-G1) - To provide improved bypass capacitors in low IF circuit. Changed C346, C349, C351 and C354.

REV. L (19D402257-G1) - To facilitate manufacturing and procurement of parts. Changed L308-L318, R366, and R372. REV. M (19D402257-G1) - To prevent squelch lock-up at high signal levels. Deleted C397. Changed CR308.

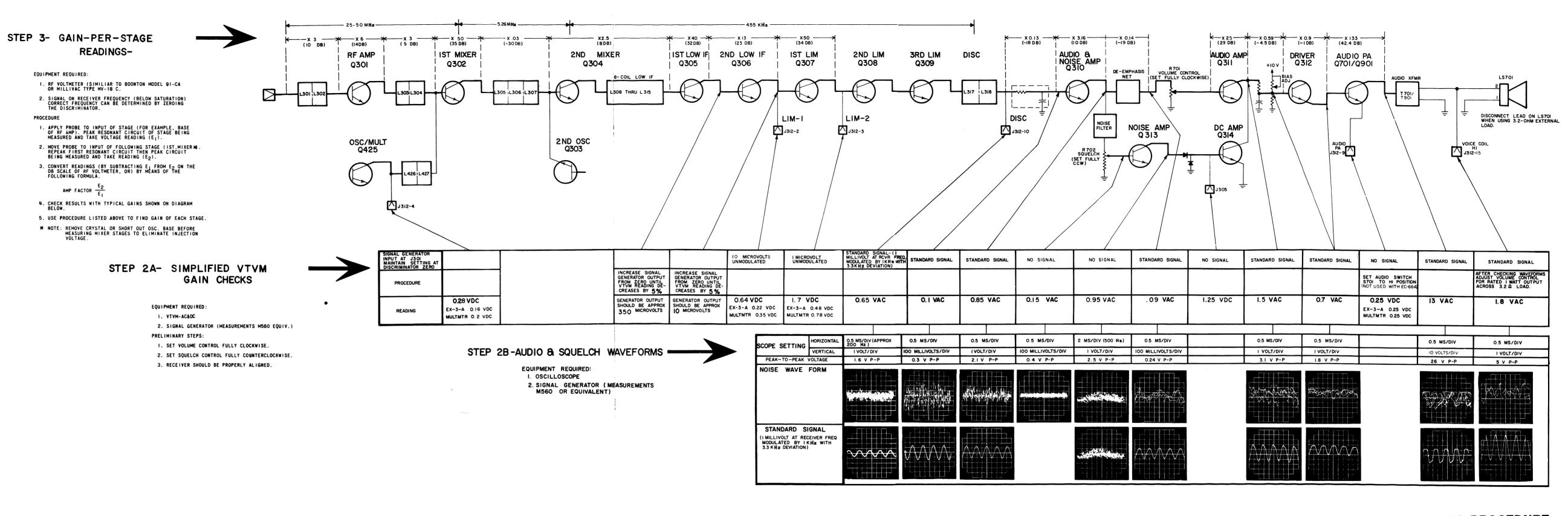
REV. N (19D402257-G1) - To improve discriminator idling and tuning. Added R379. REV. P (19D402257-G1) - To increase maximum squelch opening level. Changed the following:

C328 C336 Q310 C330 C338 Q313 C332 C340 C334

REV. R (19D402257-G1) - To improve squelch clipping. Added R381. REV. S (19D402257-G1) - To improve squelch clipping and to in-corporate new transistors. Changed Q305, Q306, Q311, Q314 and Q316 and changed R344. Deleted R381.

STEP I - QUICK CHECKS

SYMPTOM	PROCEDURE
NO SUPPLY VOLTAGE	Check power connections and continuity of supply leads, and check fuse in power supply. If fuse is blown, check receiver for short circuits.
NO REGULATED 10 VOLTS	Check the 12-volt supply. Then check regulator Q315 and regulator circuit. Resistance reading of 10-volt supply from the emitter of
LOW 2ND LIM READING	Q315 to ground should be 2 K ohms. Check supply voltages and then check oscillator reading at
DOW ZND HIM NEEDING	J312-4 as shown in STEP 2A. Make SIMPLIFIED VTVM GAIN CHECKS from 2nd Mixer through 2nd Limiter stages as shown in STEP 2A.
LOW OSCILLATOR READING	Check alignment of Oscillator (Refer to Front End Alignment Procedure).
	Check voltage and resistance reading of Oscillator Q425.
	Check crystal Y425.
LOW RECEIVER SENSITIVITY	Check Front End Alignment (Refer to Receiver Alignment Procedure).
	Check antenna connections
	Check voltage and resistance readings of RF Amp and 1st and 2nd Mixers.
	Make SIMPLIFIED GAIN CHECKS (STEP 2A).
LOW AUDIO	Check Audio PA (Q701) output current at J312-9. If reading is low
	a. Check BIAS ADJ for 0.25 VDC at J312-9 (STEP 2A).
	b. Check Q701.
	Make SIMPLIFIED GAIN and WAVEFORM CHECKS (STEPS 2A and 2B) of Audio and Squelch stages.
	Check unsquelched voltage readings in Audio section (Refer to Receiver Schematic Diagram).
	Check voltage and resistance readings on Channel Guard receiver.
IMPROPER SQUELCH OPERATION	Make GAIN and WAVEFORM CHECKS (STEPS 2A and 2B) of Audio and Squelch stages.
	Check voltage and resistance readings of Squelch circuit (Refer to Receiver Schematic Diagram).
DISCRIMINATOR IDLING TOO FAR OFF ZERO	See if discriminator zero is in the center of IF bandpass.



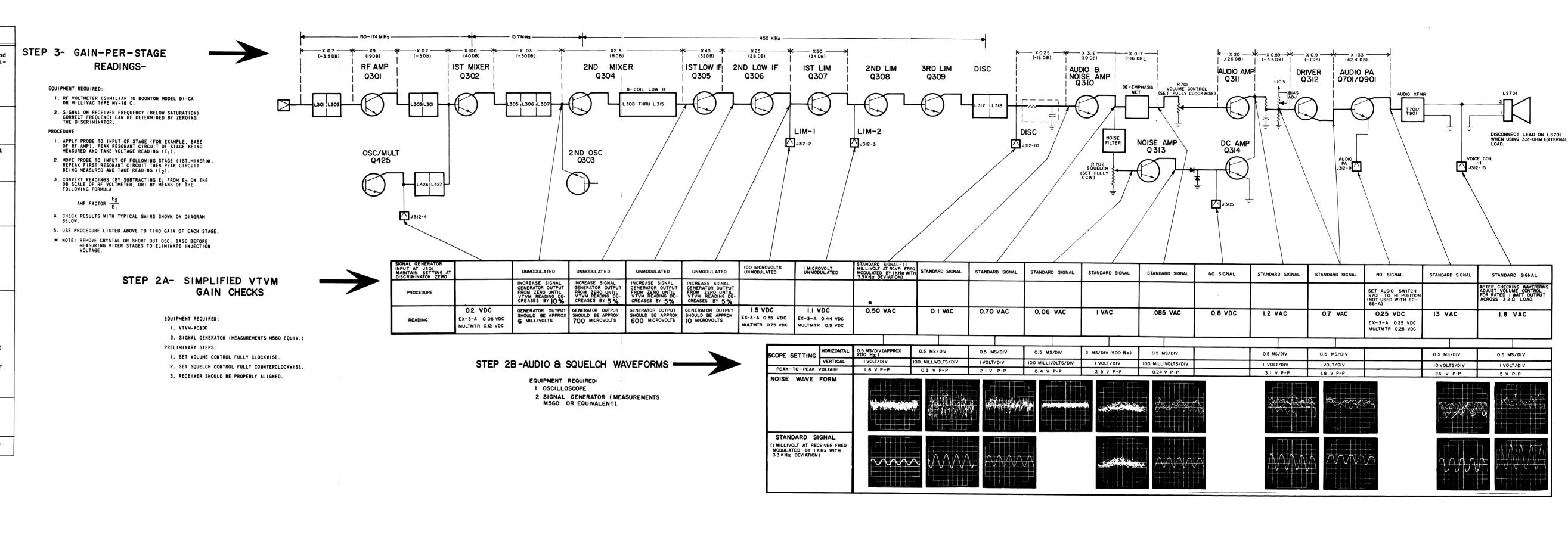
TROUBLESHOOTING PROCEDURE

25—50 MHz RECEIVER TYPE ER-51-A

RC-1482A

23

SYMPTOM	PROCEDURE
NO SUPPLY VOLTAGE	Check power connections and continuity of supply leads, an check fuse in power supply. If fuse is blown, check receiver for short circuits.
NO REGULATED 10 VOLTS	Check the 12-volt supply. Then check regulator Q315 and regulator circuit.
	Resistance reading of 10-volt supply from the emitter of Q315 to ground should be 2 K ohms.
LOW 2ND LIM READING	Check supply voltages and then check oscillator reading at J312-4 as shown in STEP 2A.
	Make SIMPLIFIED VTVM GAIN CHECKS from 2nd Mixer through 2nd Limiter stages as shown in STEP 2A.
LOW OSCILLATOR READING	Check alignment of Oscillator (Refer to Front End Alignment Procedure).
	Check voltage and resistance reading of Oscillator Q425.
	Check crystal Y425. (substitution method)
LOW RECEIVER SENSITIVITY	Check Front End Alignment (Refer to Receiver Alignment Procedure).
	Check antenna connections.
	Check voltage and resistance readings of RF Amp and 1st and 2nd Mixers.
	Make SIMPLIFIED GAIN CHECKS (STEP 2A).
LOW AUDIO	Check Audio PA (Q701) output current at J312-9. If reading is low
	a. Check BIAS ADJ for 0.25 VDC at J312-9 (STEP 2A).
	b. Check Q701.
	Make SIMPLIFIED GAIN and WAVEFORM CHECKS (STEPS 2A and 2B) of Audio and Squelch stages.
	Check unsquelched voltage readings in Audio section (Refer to Receiver Schematic Diagram).
	Check voltage and resistance readings on Channel Guard receiver.
IMPROPER SQUELCH OPERATION	Make GAIN and WAVEFORM CHECKS (STEPS 2A and 2B) of Audio and Squelch stages.
	Check voltage and resistance readings of Squelch circuit (Refer to Receiver Schematic Diagram).
DISCRIMINATOR IDLING TOO FAR OFF ZERO	See if discriminator zero is in the center of IF bandpass.



TROUBLESHOOTING PROCEDURE

132—174 MHZ RECEIVER TYPE ER-52-A

2.4

RC-1483A

ORDERING SERVICE PARTS

Each component appearing on the schematic diagram is identified by a symbol number, to simplify locating it in the parts list. Each component is listed by symbol number, followed by its description and GE Part Number.

Service Parts may be obtained from Authorized GE Communication Equipment Service Stations or through any GE Radio Communication Equipment Sales Office. When ordering a part, be sure to give:

- 1. GE Part Number for component
- 2. Description of part
- 3. Model number of equipment
- 4. Revision letter stamped on unit

These instructions do not purport to cover all details or variations in equipment nor to provide for every possible contingency to be met in connection with installation, operation or maintenance.

Should further information be desired, or should particular problems arise which are not covered sufficiently for the purchaser's purposes, contact the nearest Radio Communication Equipment Sales Office of the General Electric Company.

MAINTENANCE MANUAL

LBI-3757

MOBILE RADIO DEPARTMENT
GENERAL ELECTRIC COMPANY ● LYNCHBURG, VIRGINIA 24502

